



Elektrische Eigenschaften / Electrical properties

Höchstzulässige Werte / Maximum rated values

Periodische Vorwärts- und Rückwärts-Spitzensperrspannung repetitive peak forward off-state and reverse voltages	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj\text{ max}}$	$V_{\text{DRM}}, V_{\text{RRM}}$	2000 2400	2200 2600 2800	V V V
Vorwärts-Stoßspitzensperrspannung non-repetitive peak forward off-state voltage	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj\text{ max}}$	V_{DSM}	2000 2400	2200 2600 2800	V V V
Rückwärts-Stoßspitzensperrspannung non-repetitive peak reverse voltage	$T_{vj} = +25^{\circ}\text{C} \dots T_{vj\text{ max}}$	V_{RSM}	2100 2500	2300 2700 2900	V V V
Durchlaßstrom-Grenzeffektivwert RMSM on-state current		I_{TRSM}		2625	A
Dauergrenzstrom average on-state current	$T_{\text{C}} = 85^{\circ}\text{C}$ $T_{\text{C}} = 61^{\circ}\text{C}$	I_{TAVM}		1220 1670,9	A A
Stoßstrom-Grenzwert surge current	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ ms}$ $T_{vj} = T_{vj\text{ max}}, t_p = 10\text{ ms}$	I_{TSM}		25000 22500	A A
Grenzlastintegral I^2t -value	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ ms}$ $T_{vj} = T_{vj\text{ max}}, t_p = 10\text{ ms}$	I^2t		3125 2531	$\text{A}^2\text{s} \cdot 10^3$ $\text{A}^2\text{s} \cdot 10^3$
Kritische Stromsteilheit critical rate of rise of on-state current	DIN IEC 747-6 $f=50\text{ Hz}, V_L = 10\text{ V}, i_{\text{GM}} = 1\text{ A}$ $di_{\text{G}}/dt = 1\text{ A}/\mu\text{s}$	$(di_{\text{T}}/dt)_{\text{cr}}$		150	$\text{A}/\mu\text{s}$
Kritische Spannungssteilheit critical rate of rise of off-state voltage	$T_{vj} = T_{vj\text{ max}}, V_D = 0,67 V_{\text{DRM}}$ 5.Kennbuchstabe / 5th letter F	$(dv_{\text{D}}/dt)_{\text{cr}}$		1000	$\text{V}/\mu\text{s}$

Charakteristische Werte / Characteristic values

Durchlaßspannung on-state voltage	$T_{vj} = T_{vj\text{ max}}, i_{\text{T}} = 3,50\text{ kA}$ $T_{vj} = T_{vj\text{ max}}, i_{\text{T}} = 1\text{ kA}$	v_{T} v_{T}	max. max.	2,13 1,38	V V
Schleusenspannung threshold voltage	$T_{vj} = T_{vj\text{ max}}$	$V_{\text{T(TO)}}$		1	V
Ersatzwiderstand slope resistance	$T_{vj} = T_{vj\text{ max}}$	r_{T}		0,2750	$\text{m}\Omega$
Durchlaßkennlinie on-state voltage $v_{\text{T}} = A + B \times i_{\text{T}} + C \times \ln(i_{\text{T}} + 1) + D \times \sqrt{i_{\text{T}}}$	$T_{vj} = T_{vj\text{ r}}$	A= 0,9686992 B= 2,17E-04 C= -0,0096522 D= 8,13E-03			
Zündstrom gate trigger current	$T_{vj} = 25^{\circ}\text{C}, V_D = 6\text{ V}$	I_{GT}	max.	250	mA
Zündspannung gate trigger voltage	$T_{vj} = 25^{\circ}\text{C}, V_D = 6\text{ V}$	V_{GT}	max.	2	V
Nicht zündener Steuerstrom gate non-trigger current	$T_{vj} = T_{vj\text{ max}}, V_D = 6\text{ V}$ $T_{vj} = T_{vj\text{ max}}, V_D = 0,5 V_{\text{DRM}}$	I_{GD}	max. max.	10 5	mA mA
Nicht zündene Steuerspannung gate non-trigger voltage	$T_{vj} = T_{vj\text{ max}}, V_D = 0,5 V_{\text{DRM}}$	V_{GD}	max.	0,25	mV
Haltestrom holding current	$T_{vj} = 25^{\circ}\text{C}, V_D = 6\text{ V}, R_A = 5\ \Omega$	I_{H}	max.	500	mA
Einraststrom latching current	$T_{vj} = 25^{\circ}\text{C}, V_D = 6\text{ V}, R_{\text{GK}} \geq 10\ \Omega$ $i_{\text{GM}} = 1\text{ A}, di_{\text{G}}/dt = 1\text{ A}/\mu\text{s}$ $t_{\text{g}} = 20\ \mu\text{s}$	I_{L}	max.	2500	mA
Vorwärts- und Rückwärts-Sperrstrom forward off-state and reverse currents	$T_{vj} = T_{vj\text{ max}}$ $V_D = V_{\text{DRM}}, V_R = V_{\text{RRM}}$	$i_{\text{D}}, i_{\text{R}}$	max.	200	mA
Zündverzug gate controlled delay time	DIN IEC 747-6 $T_{vj} = 25^{\circ}\text{C}$ $i_{\text{GM}} = 1\text{ A}, di_{\text{G}}/dt = 1\text{ A}/\mu\text{s}$	t_{gd}	max.	4,5	μs



Elektrische Eigenschaften / Electrical properties

Charakteristische Werte / Characteristic values

Freiwerdezeit circuit commutated turn-off time	$T_{vj} = T_{vj\ max}, t_{TM} = t_{TAVM}$ $V_{RM} = 100V, V_{DM} = 0,67 V_{DRM}$ $dv_p/dt = 20 V/\mu s, -di_T/dt = 10 A/\mu s$ 4. Kennbuchstabe / 4th letter O	t_q	typ.	350	μs
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Thermische Eigenschaften / Thermal properties

Innerer Wärmewiderstand thermal resistance, junction to case	Kühlfläche / cooling surface beidseitig / two-sided, $\varphi = 180^\circ \sin$ beidseitig / two-sided, DC Anode / anode, $\varphi = 180^\circ \sin$ Anode / anode, DC Kathode / cathode, $\varphi = 180^\circ \sin$ Kathode / cathode, DC	R_{thJC}	max.	0,0184	$^\circ C/W$
			max.	0,0170	$^\circ C/W$
			max.	0,0344	$^\circ C/W$
			max.	0,0330	$^\circ C/W$
			max.	0,0364	$^\circ C/W$
			max.	0,0350	$^\circ C/W$
Übergangs- Wärmewiderstand thermal resistance, case to heatsink	Kühlfläche / cooling surface beidseitig / two-sided einseitig / single-sided	R_{thJK}	max.	0,0035	$^\circ C/W$
			max.	0,0070	$^\circ C/W$
Höchstzulässige Sperrschichttemperatur max. junction temperature		$T_{vj\ max}$		125	$^\circ C$
Betriebstemperatur operating temperature		$T_{c\ op}$		-40,,,+125	$^\circ C$
Lagertemperatur storage temperature		T_{stg}		-40,,,+150	$^\circ C$

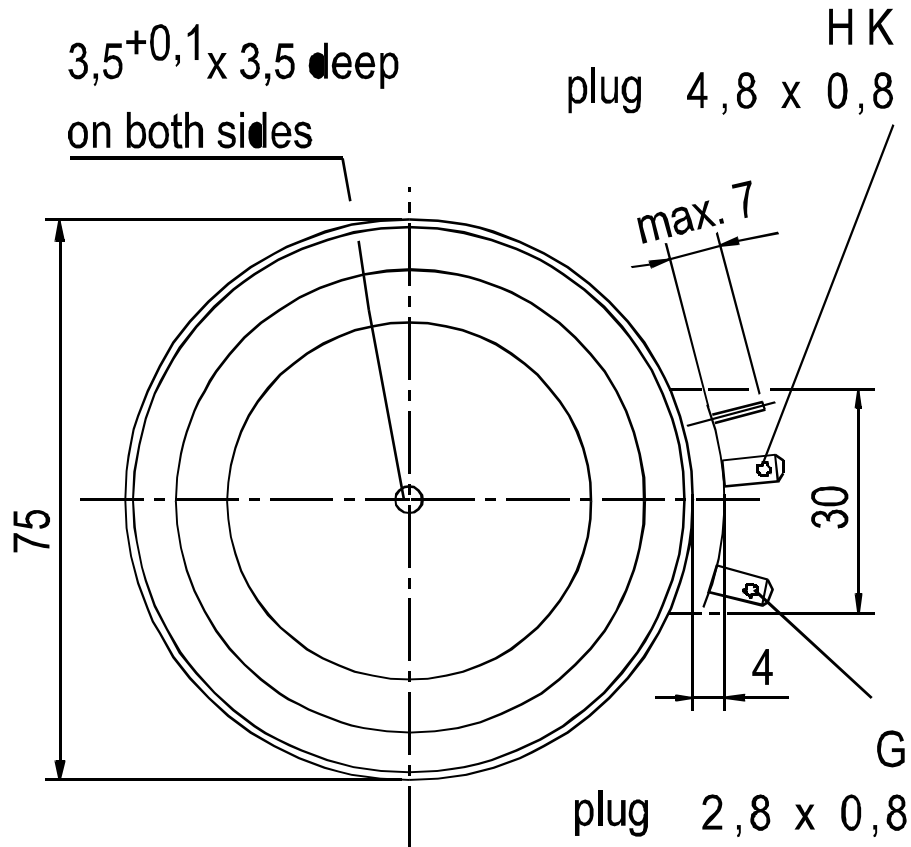
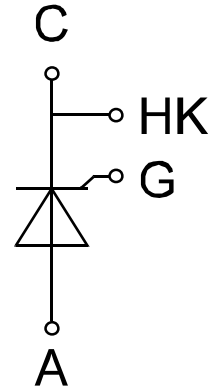
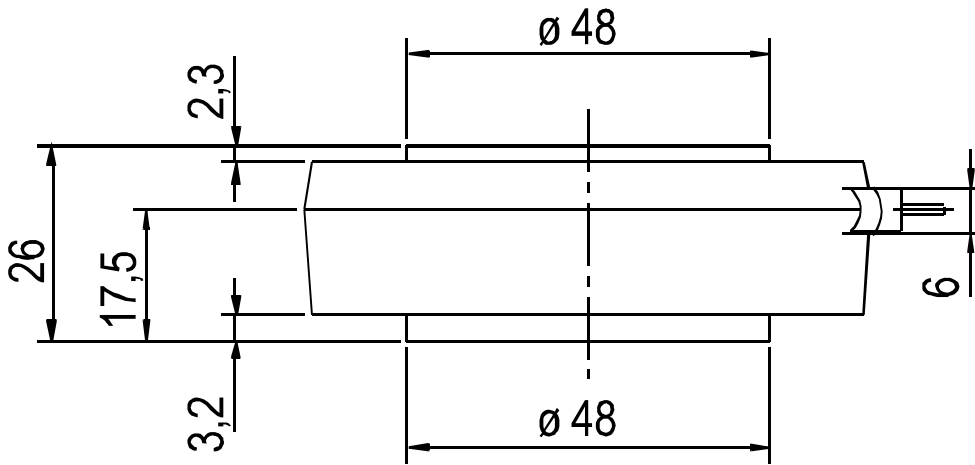
Mechanische Eigenschaften / Mechanical properties

Gehäuse, siehe Anlage case, see appendix				Seite 3 page 3	
Si-Element mit Druckkontakt Si-pellet with pressure contact					
Anpreßkraft clamping force		F		20...45	kN
Gewicht weight		G	typ.	540	g
Kriechstrecke creepage distance				32	mm
Feuchtklasse humidity classification	DIN 40040			C	
Schwingfestigkeit vibration resistance	f = 50Hz			50	m/s ²

Mit dieser technischen Information werden Halbleiterbauelemente spezifiziert, jedoch keine Eigenschaften zugesichert. Sie gilt in Verbindung mit den zugehörigen Technischen Erläuterungen./ The technical information specifies semiconductor devices but promises no characteristics. It is valid in combination with the belonging technical notes.

Netz-Thyristor
Phase Control Thyristor

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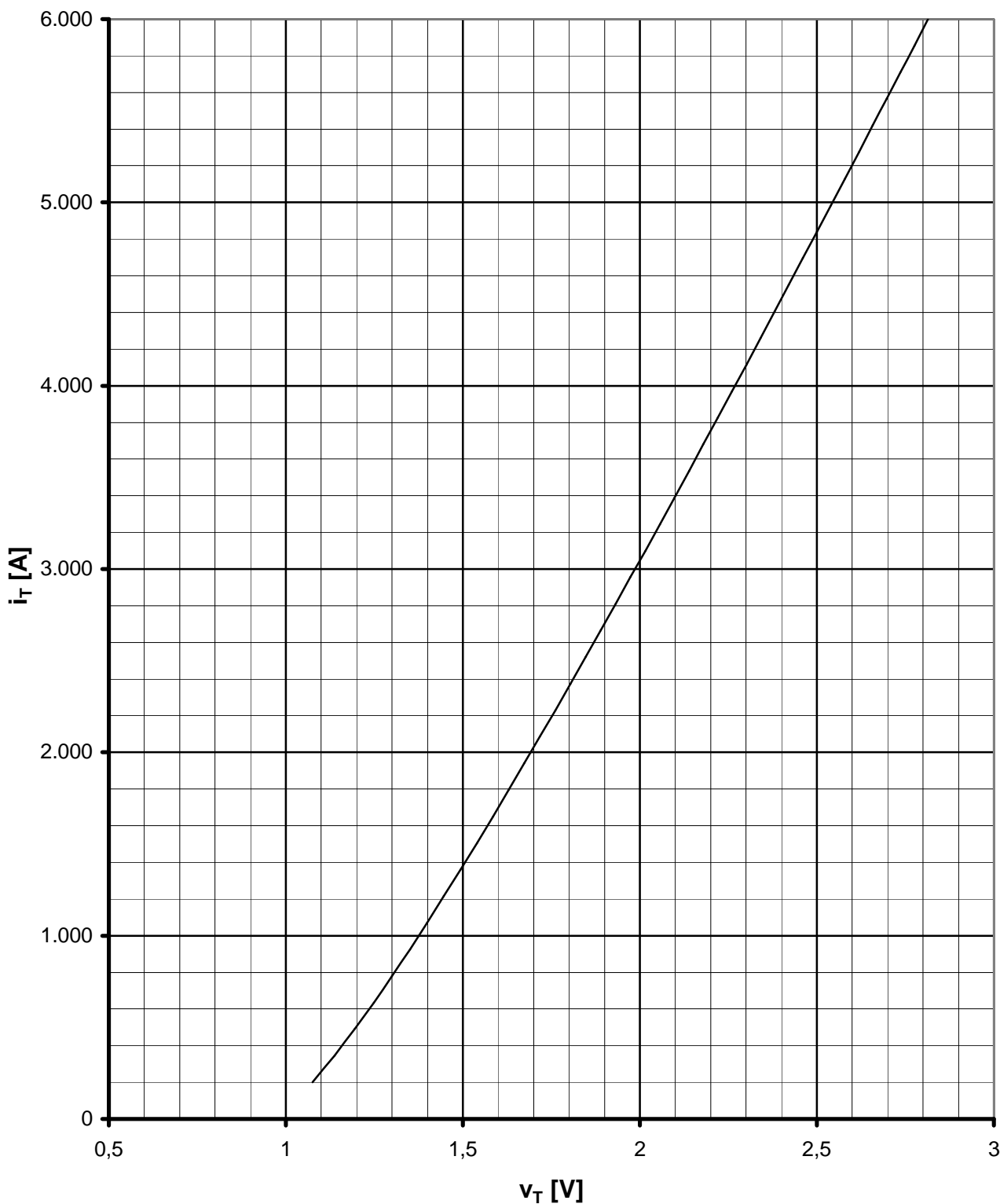
Kühlung cooling	Analytische Elemente des transienten Wärmewiderstandes Z_{thJC} für DC Analytical elements of transient thermal impedance Z_{thJC} for DC							
	Pos.n	1	2	3	4	5	6	7
beidseitig two-sided	R_{thn} [°C/W]	0,000220	0,000000	0,001020	0,002830	0,006080	0,00575	
	τ_n [s]	0,001360	0,003060	0,013900	0,066200	0,512000	1,490	
anodenseitig anode-sided	R_{thn} [°C/W]	0,000650	0,001900	0,002390	0,003810	0,004250	0,02000	
	τ_n [s]	0,001600	0,009100	0,079100	0,260000	1,736000	7,210	
kathodenseitig cathode-sided	R_{thn} [°C/W]	0,000550	0,002060	0,006040	0,005510	0,020840		
	τ_n [s]	0,001400	0,008570	0,154000	2,580000	7,0070		

Analytische Funktion / analytical function : $Z_{thJC} = \sum_{n=1}^{n_{max}} R_{thn} (1 - EXP (- t / \tau_n))$

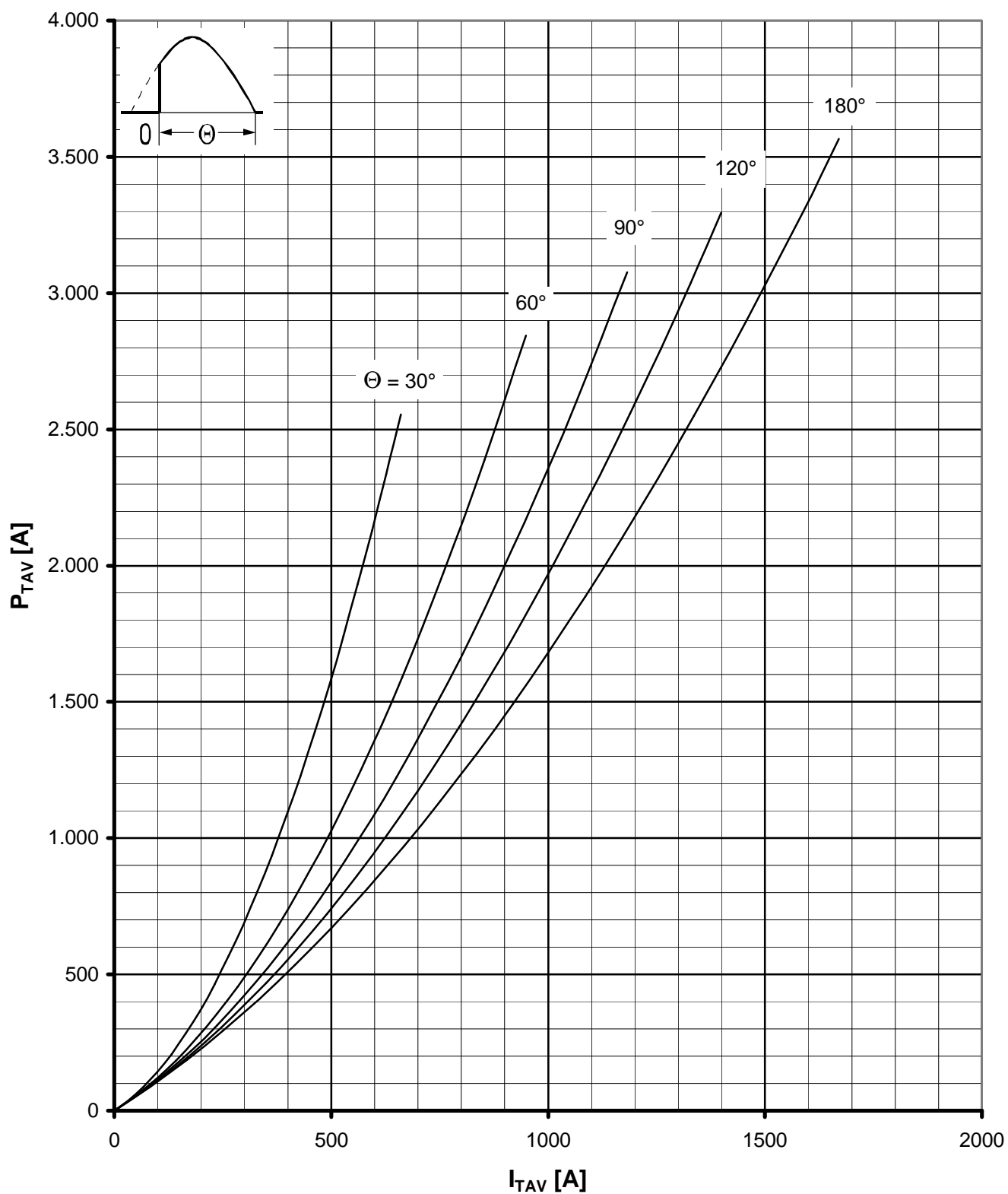
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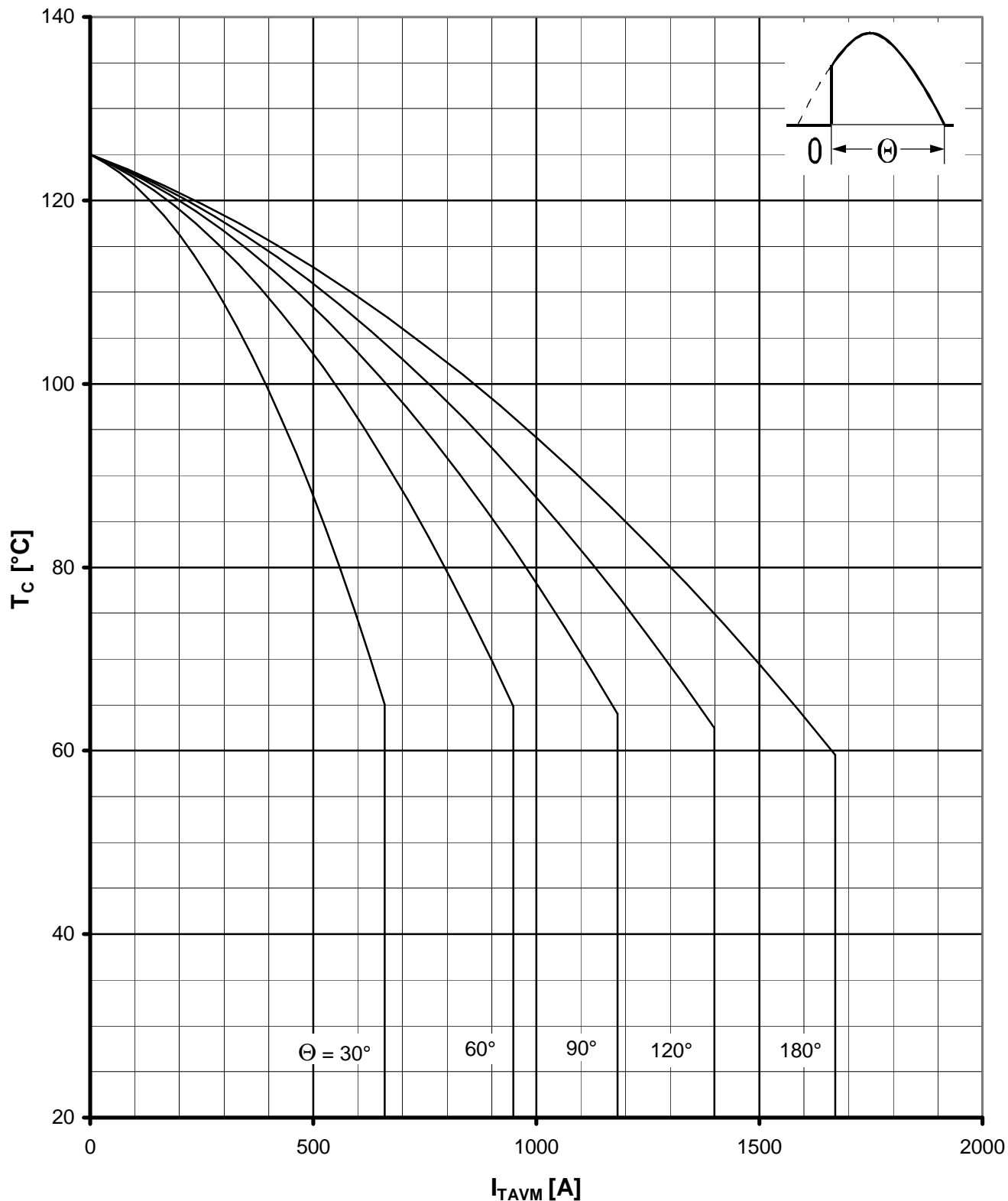
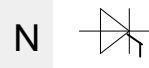
Grenzdurchlaßkennlinie / Limiting On-state characteristic $i_T = f(v_T)$
 $T_{vj} = T_{vj} \text{ max}$



Durchlaßverlustleistung / On-state power loss $P_{TAV} = f(I_{TAV})$
 Parameter: Stromflußwinkel Θ / current conduction angle Θ

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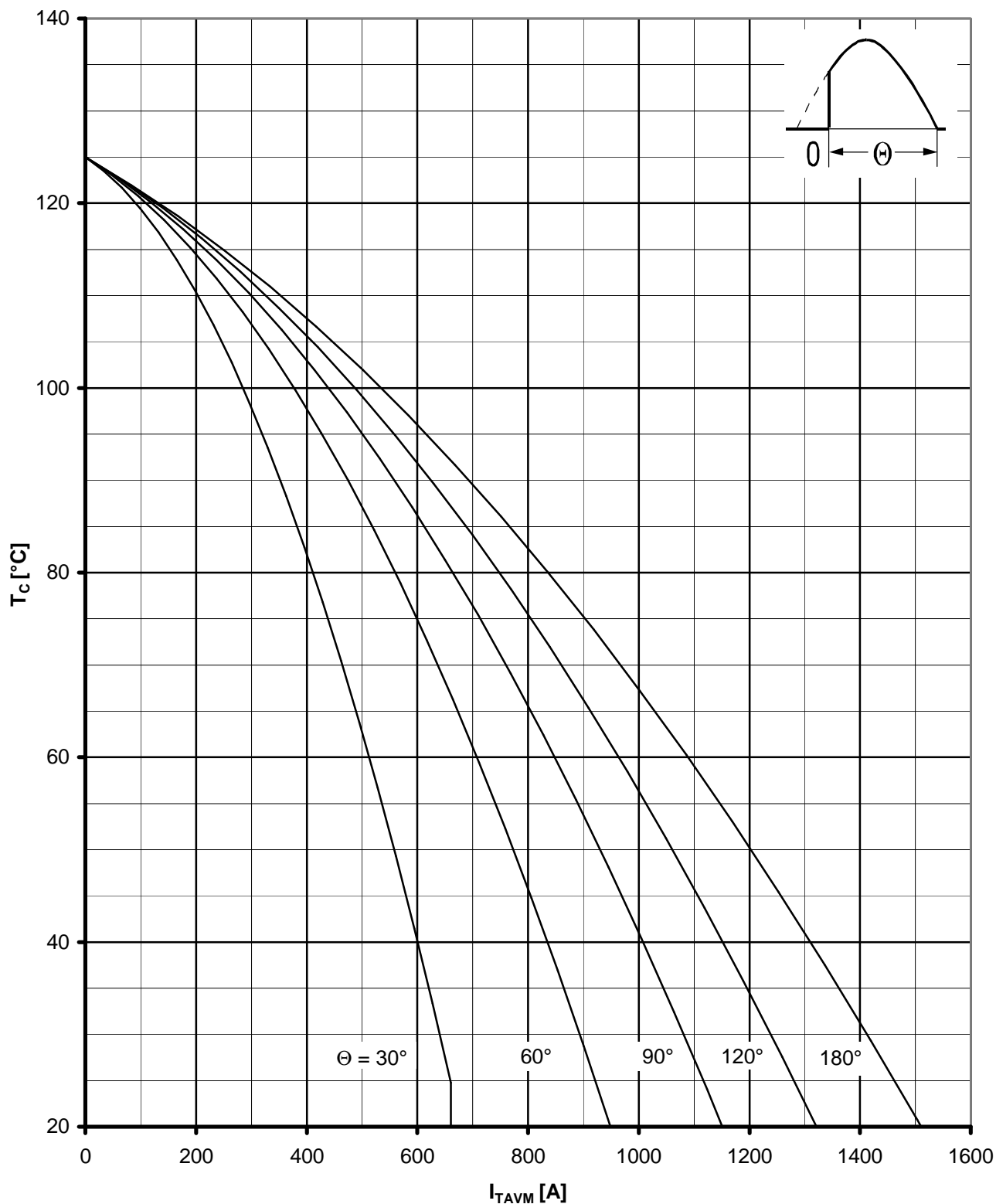
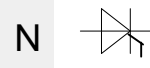
Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_c = f(I_{TAVM})$

Beidseitige Kühlung / Two-sided cooling

Parameter: Stromflußwinkel Θ / current conduction angle Θ

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Phase Control Thyristor

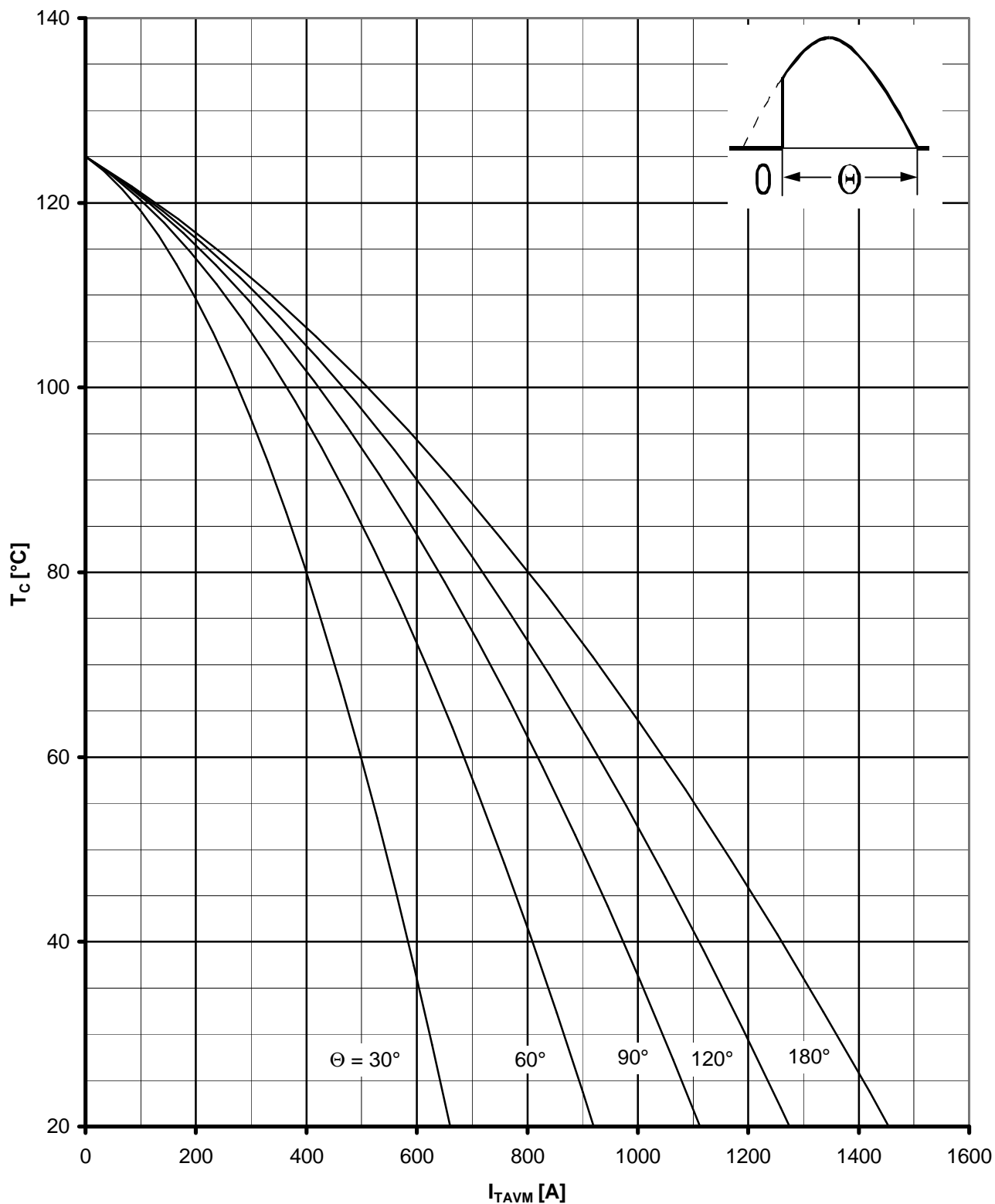
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Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_c = f(I_{TAVM})$

Anodenseitige Kühlung / anode sided cooling

Parameter: Stromflußwinkel θ / current conduction angle θ



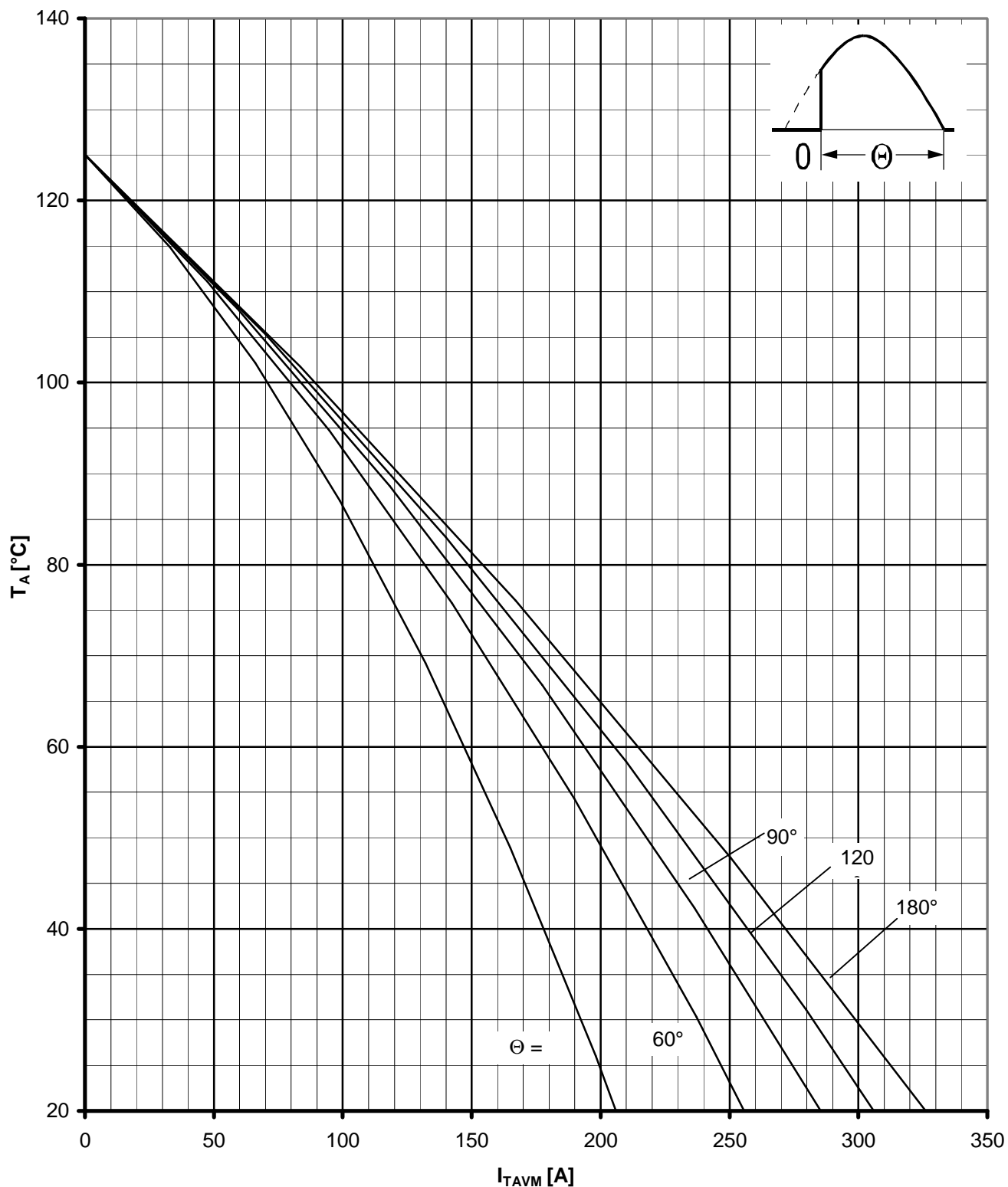
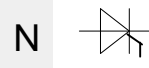
Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{TAVM})$

Kathodenseitige Kühlung / cathode sided cooling

Parameter: Stromflußwinkel θ / current conduction angle θ

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Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$

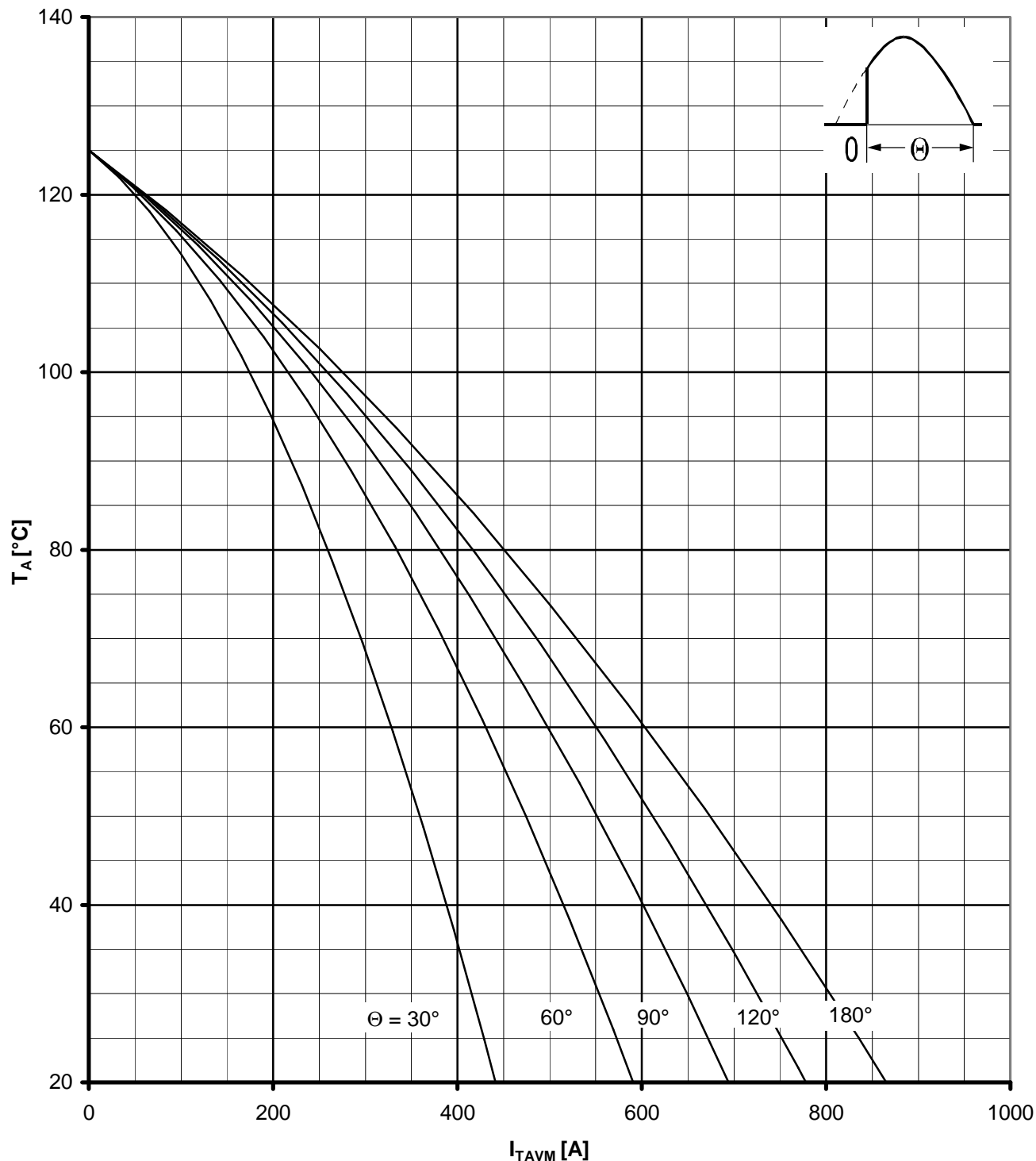
Luftselbstkühlung / Natural air-cooling

Kühlkörper/Heatsink. K0.05F

Parameter: Stromflußwinkel θ / current conduction angle θ

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Phase Control Thyristor

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Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$

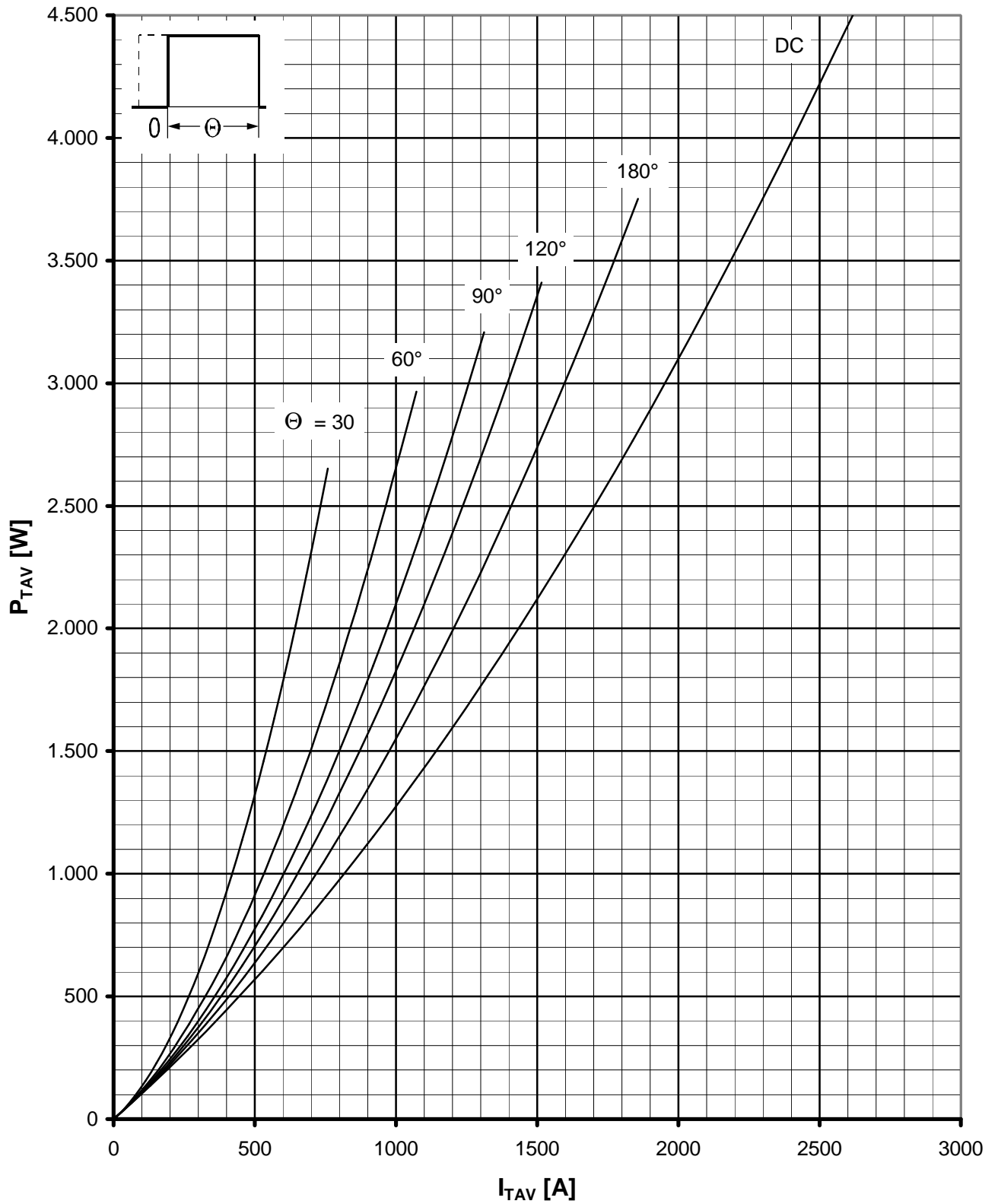
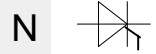
Verstärkte Luftkühlung / Forced air-cooling

Kühlkörper/Heatsink. K0.05F, $T_A = 35$ °C, $V_L = 120$ l/s

Parameter: Stromflußwinkel θ / current conduction angle θ

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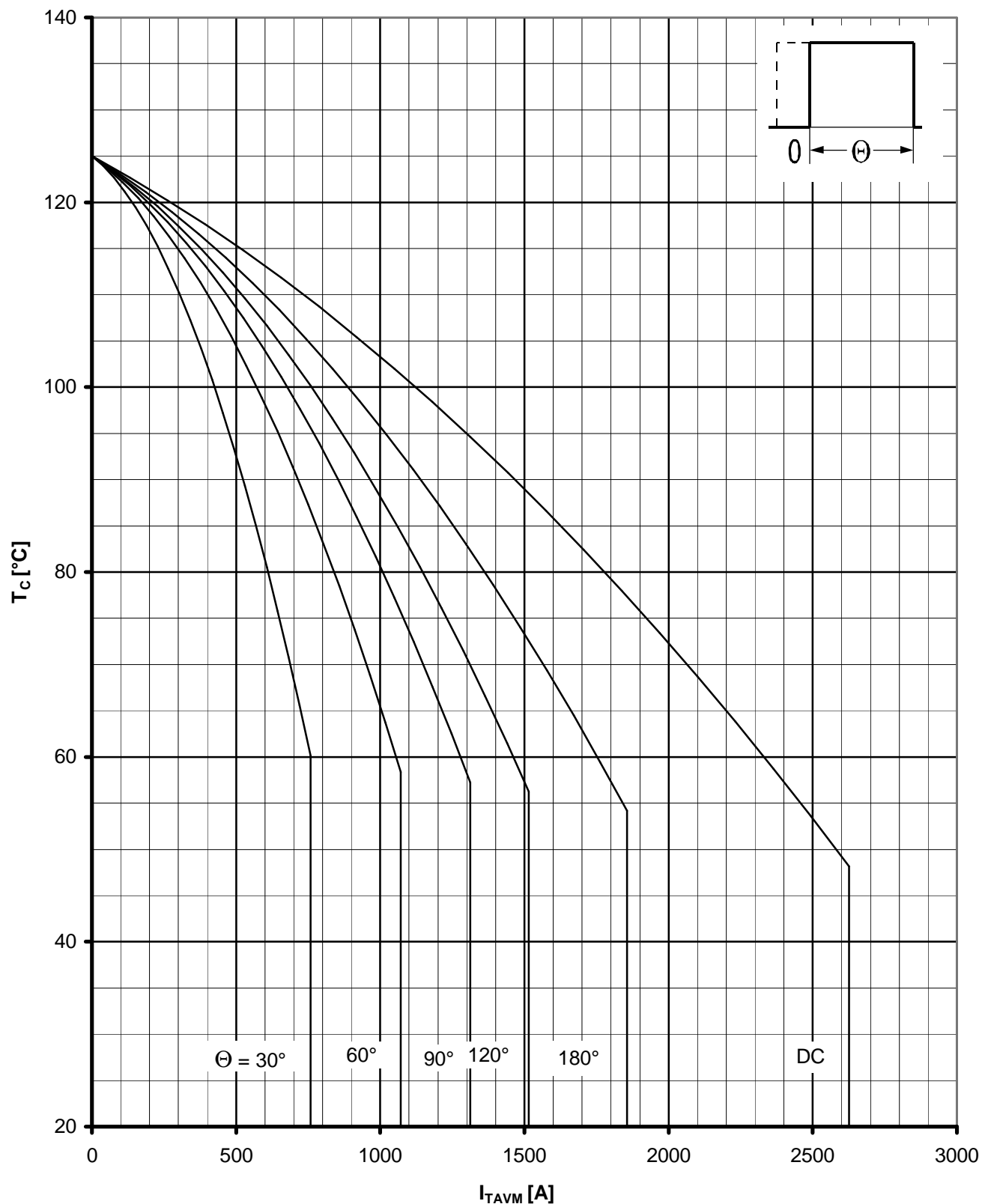
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Durchlaßverlustleistung / On-state power loss $P_{TAV} = f(I_{TAV})$
Parameter: Stromflußwinkel Θ / current conduction angle Θ

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Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{TAVM})$

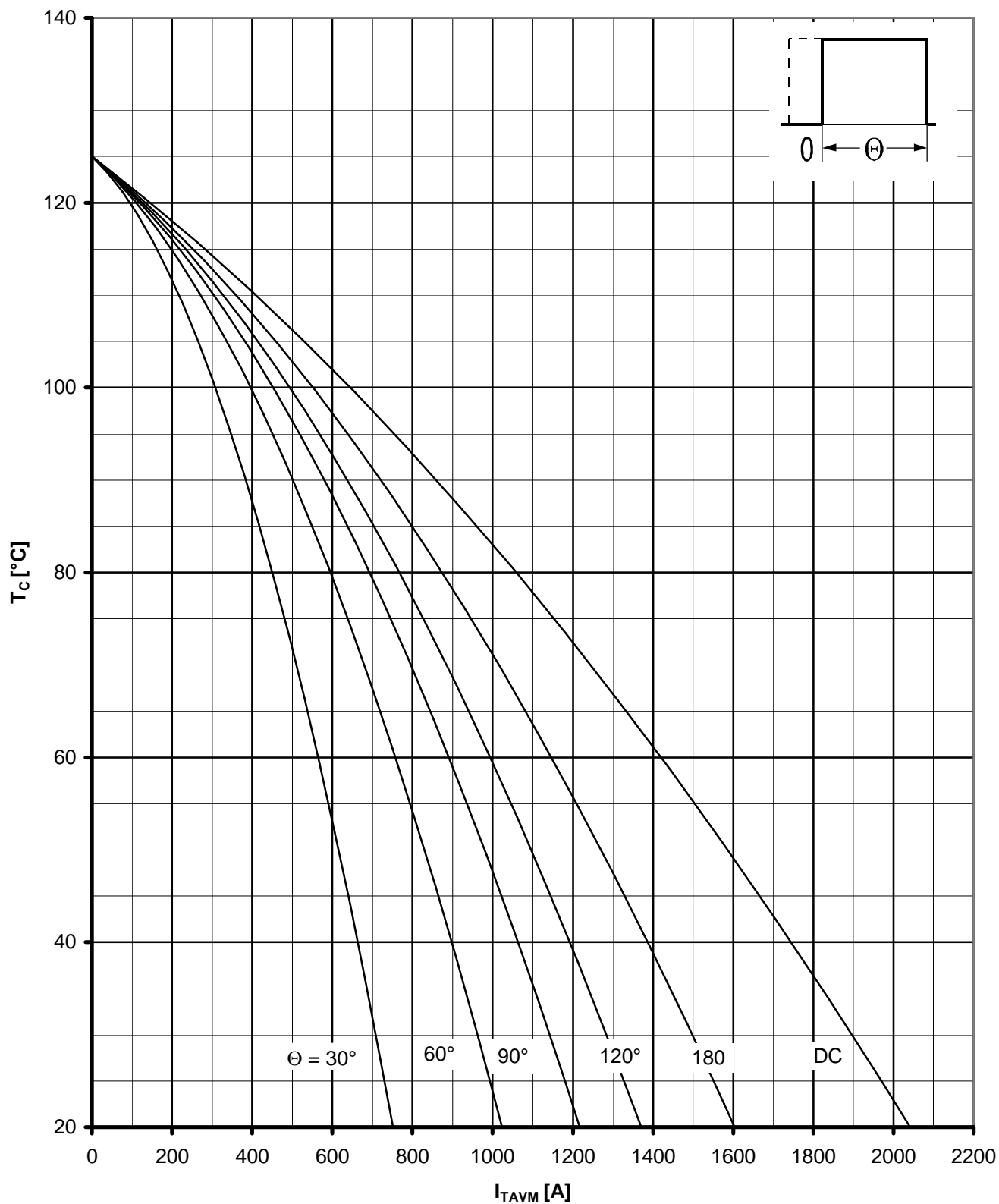
Beidseitige Kühlung / Two-sided cooling

Parameter: Stromflußwinkel Θ / current conduction angle Θ

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Phase Control Thyristor

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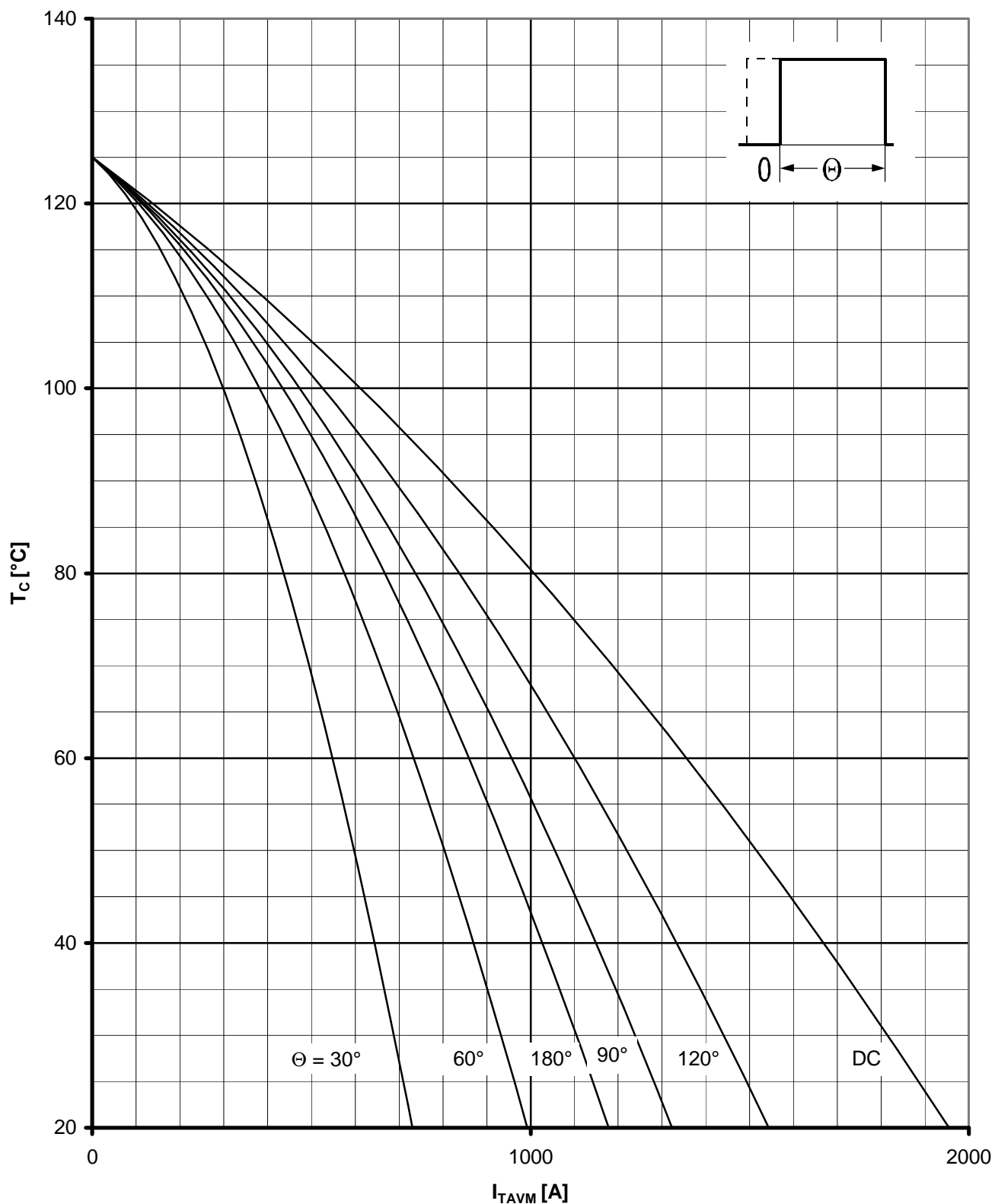
Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_c = f(I_{TAVM})$

Anodenseitige Kühlung / anode sided cooling

Parameter: Stromflußwinkel θ / current conduction angle θ

Netz-Thyristor
Phase Control Thyristor

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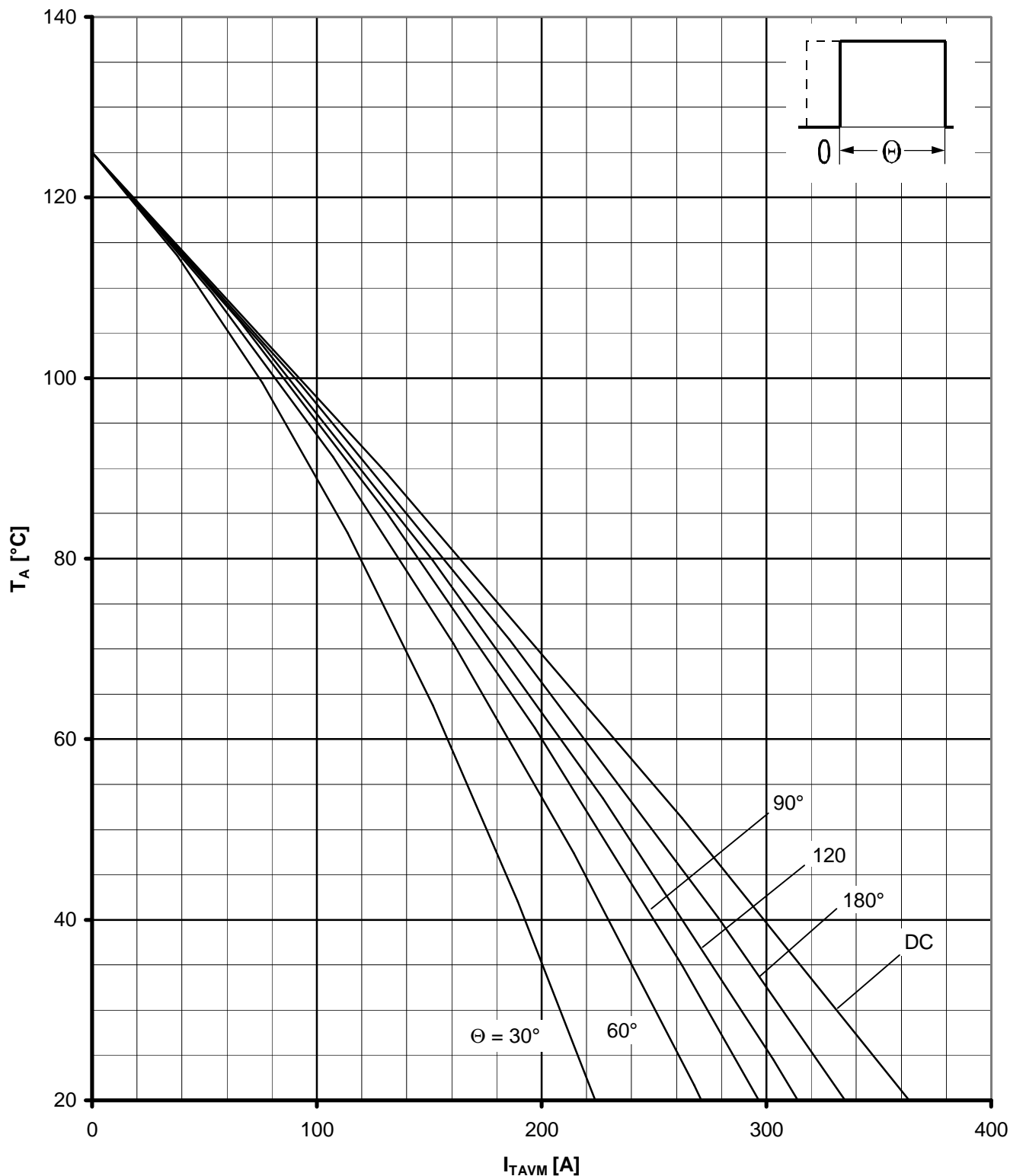
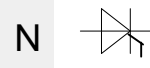
Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_c = f(I_{TAVM})$

Kathodenseitige Kühlung / cathode sided cooling

Parameter: Stromflußwinkel θ / current conduction angle θ

Netz-Thyristor
Phase Control Thyristor

T 1219 N 20...28



Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$

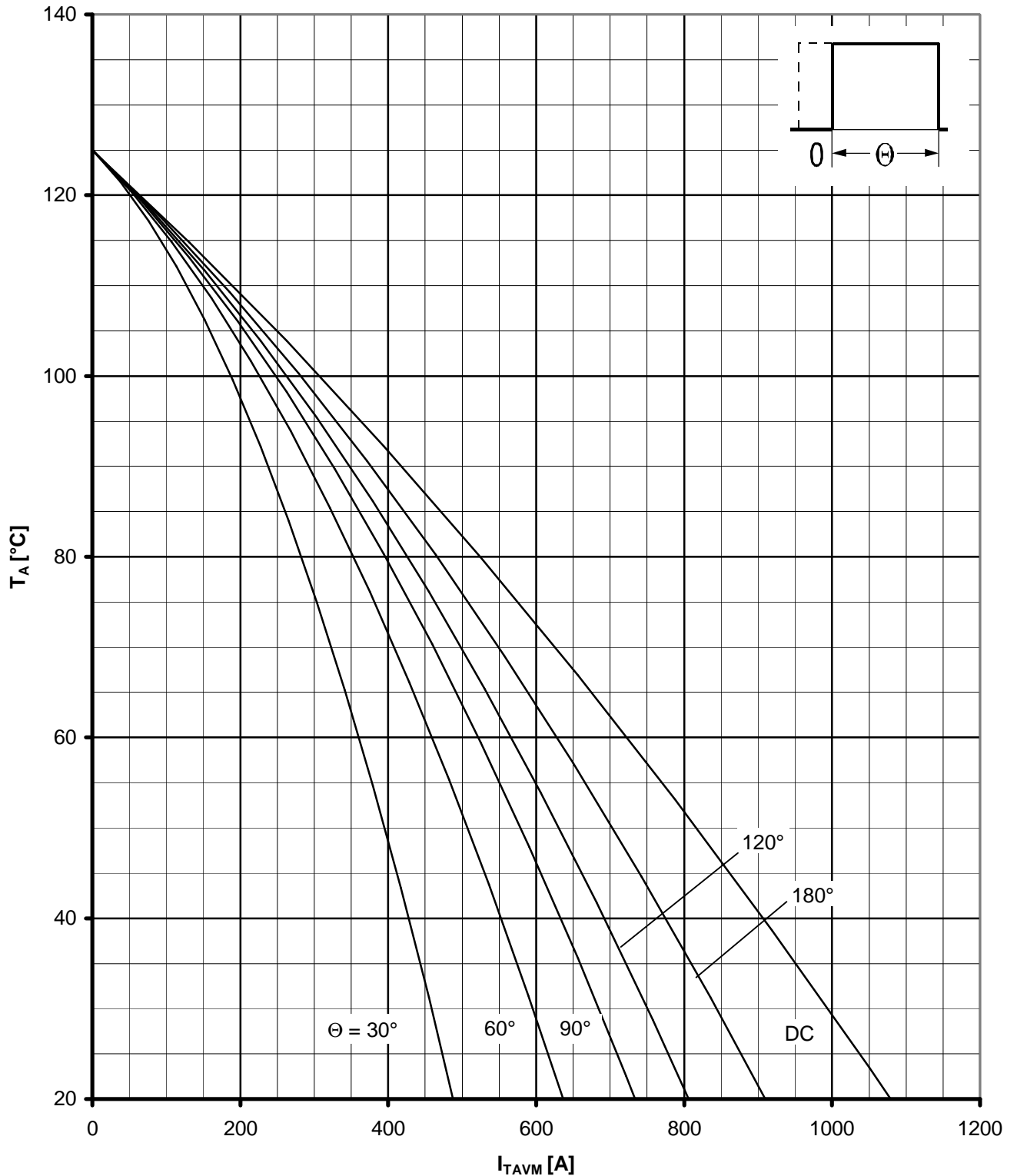
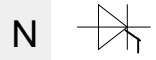
Luftselbstkühlung / Natural air-cooling

Kühlkörper/Heatsink. K0.05 F

Parameter: Stromflußwinkel Θ / current conduction angle Θ

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Phase Control Thyristor

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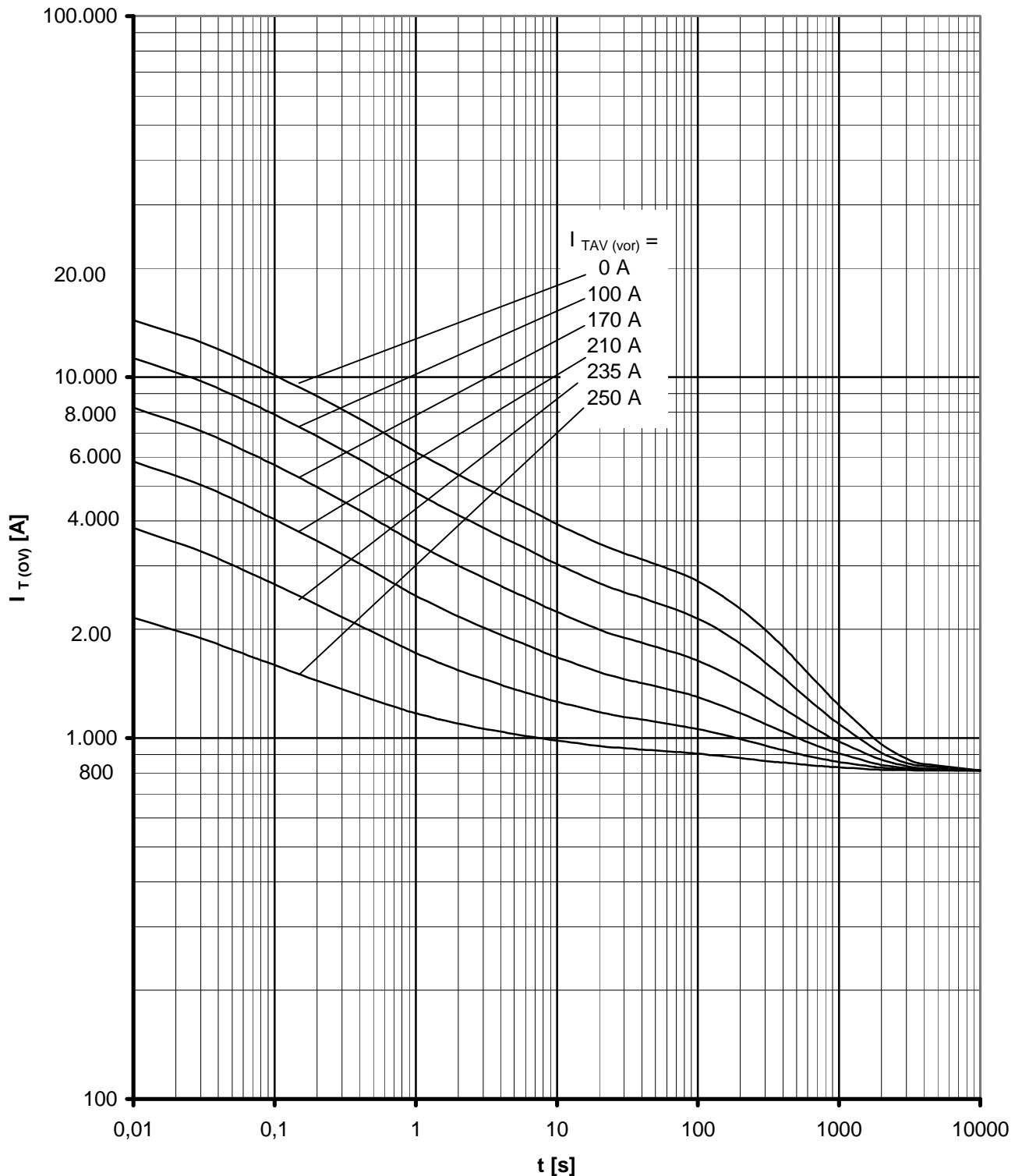


Hochstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$

Verstärkte Luftkühlung / Forced air-cooling

Kühlkörper/Heatsink. K0.05F, $V_L = 120$ l/s

Parameter: Stromflußwinkel θ / current conduction angle θ

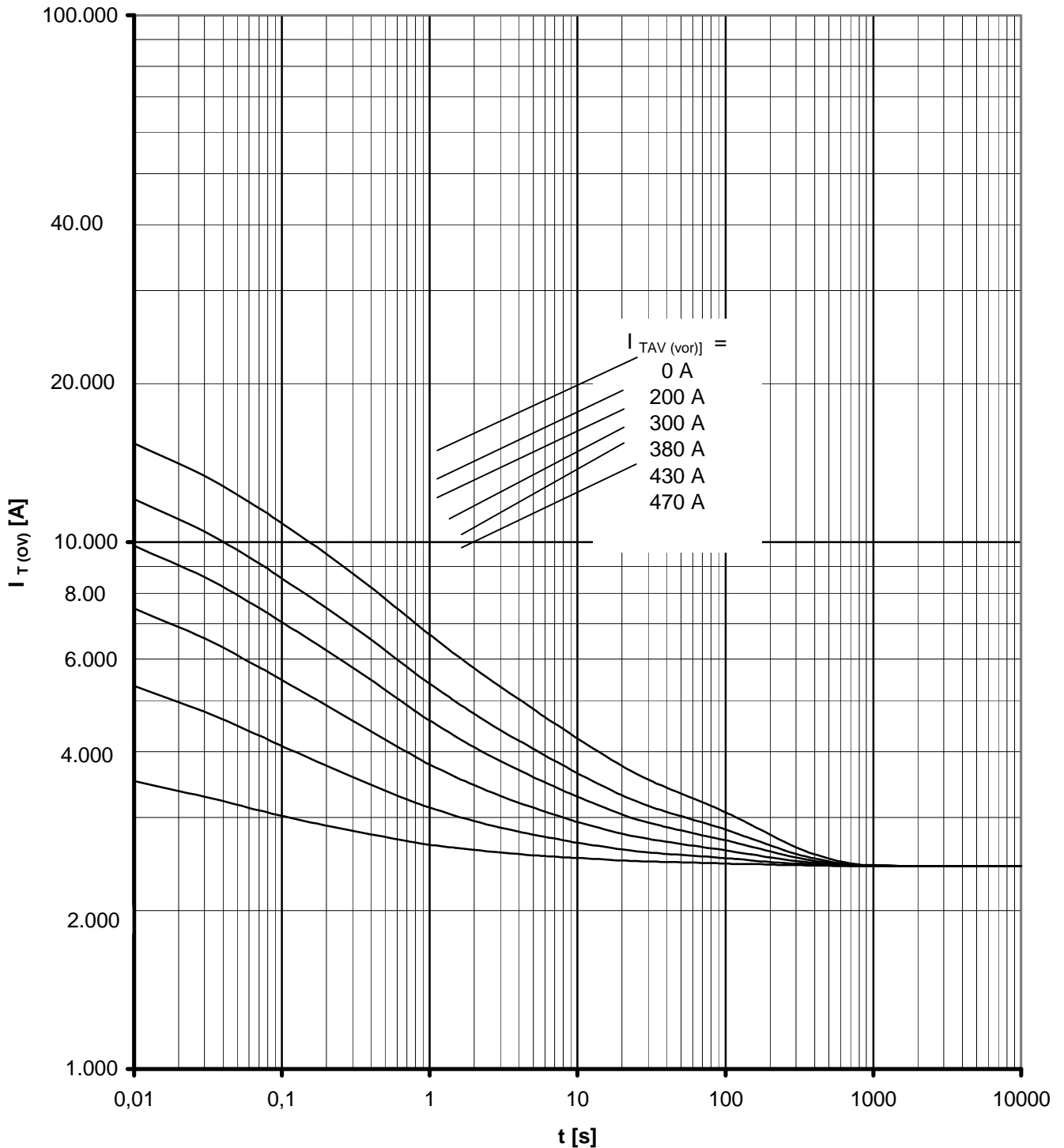


Überstrom / Overload on-state current $I_{T(OV)} = f(t)$

Beidseitige Luftselbstkühlung / Two-sided natural cooling K0.05F

$T_A = 45^\circ\text{C}$

Parameter: Vorlaststrom / pre-load current $I_{TAV(vor)}$



Überstrom / Overload on-state current $I_{T(OV)} = f(t)$

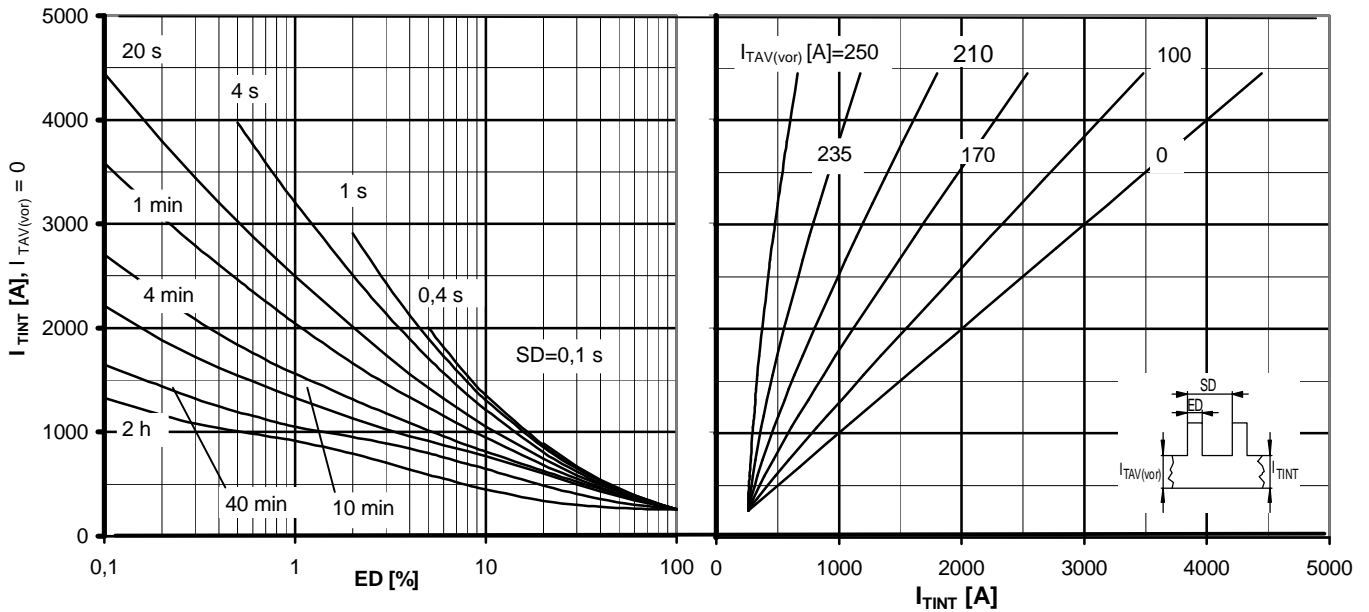
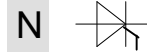
Beidseitige verstärkte Kühlung / forced two-sided cooling K0.05F

$T_A = 35^\circ\text{C}$, $V_L = 120$ l/s

Parameter: Vorlaststrom / pre-load current $I_{TAV(vor)}$

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Phase Control Thyristor

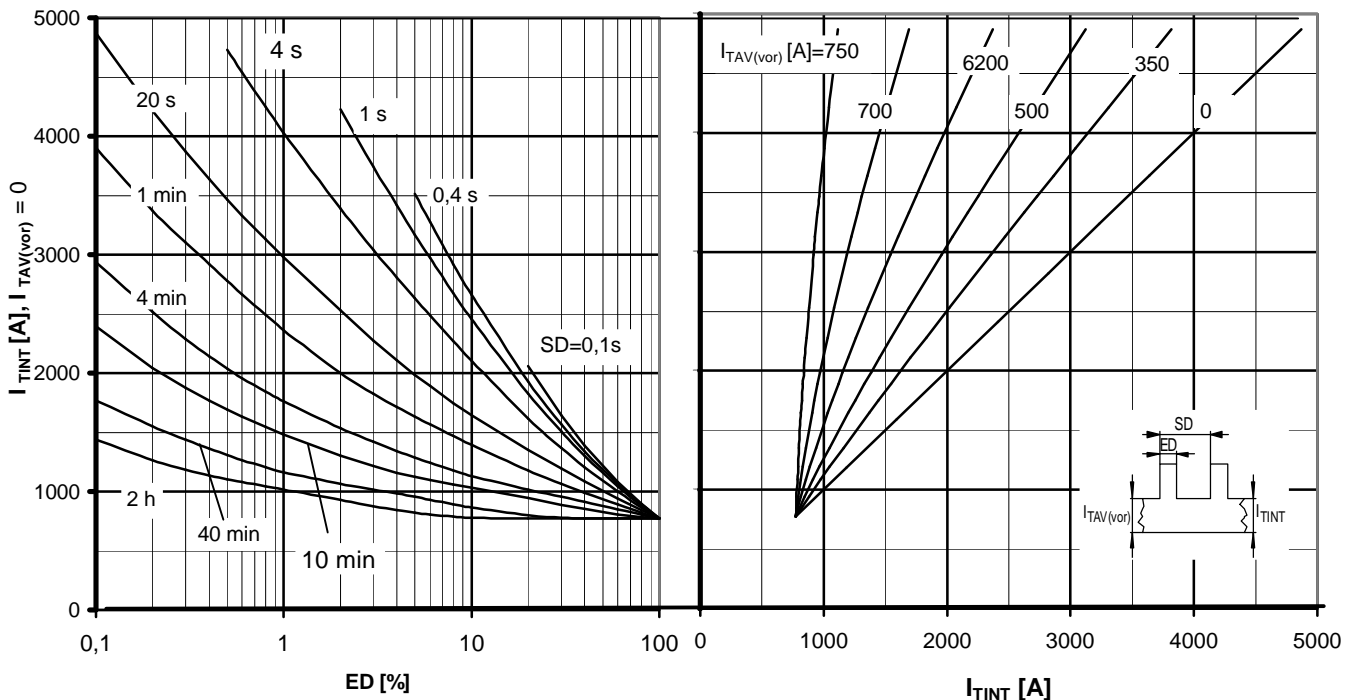
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Höchstzul. Durchlaßstrom bei Ausetzbetrieb / Max. allowable on-state current during intermittent operation $I_{TINT} = f(ED)$

Beidseitig Luftselbstkühlung / two-sided natural cooling $K 0.048F$
 $T_A = 45\text{ °C}$

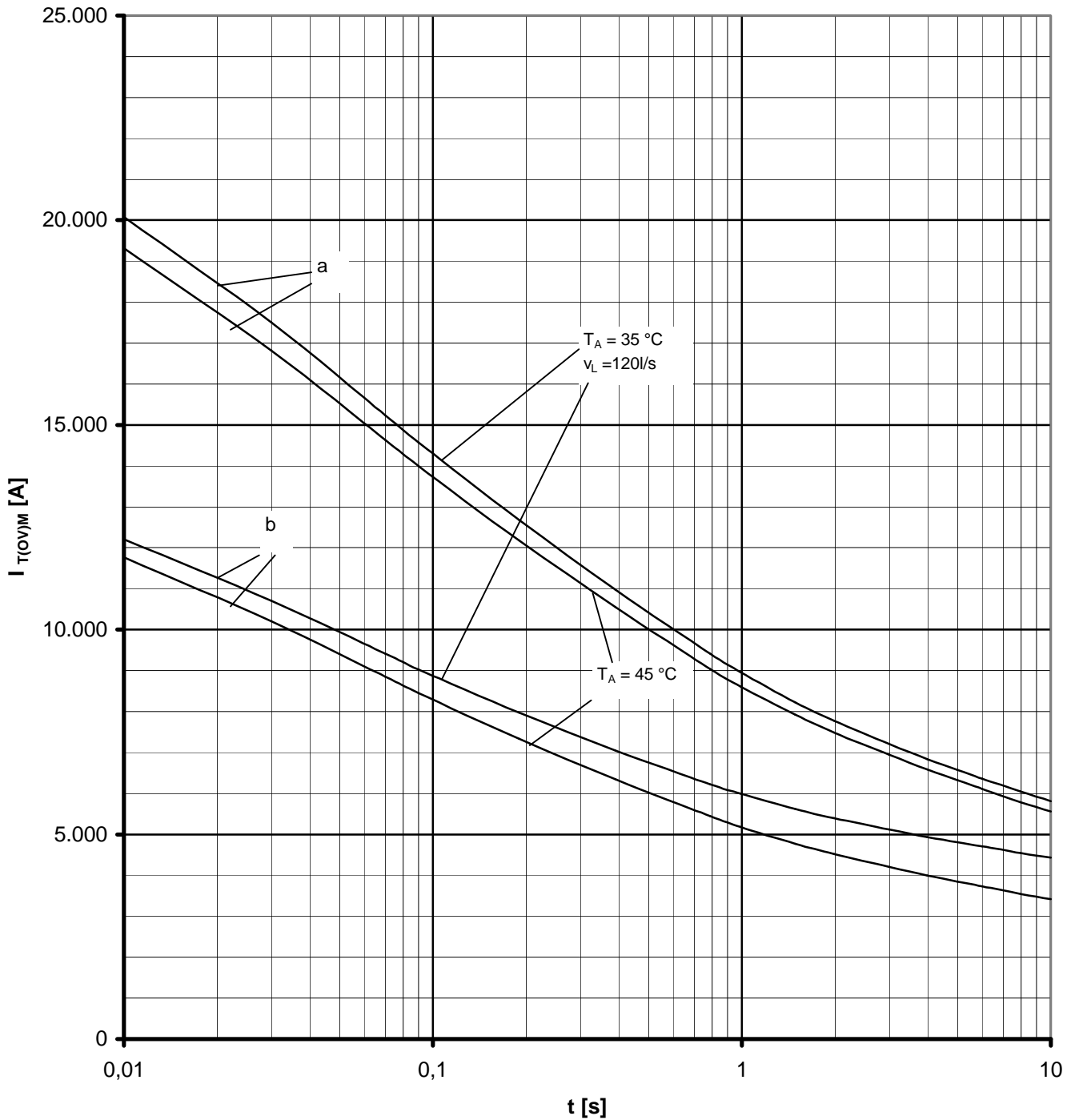
Parameter: Vorlaststrom / pre-load current $I_{TAV(vor)}$, Spieldauer / cycle duration SD



Höchstzul. Durchlaßstrom bei Ausetzbetrieb / Max. allowable on-state current during intermittent operation $I_{TINT} = f(ED)$

Beidseitig verstärkte Kühlung / forced two-sided cooling $K 0.048F$
 $T_A = 35\text{ °C}$, $V_L = 120\text{ l/s}$

Parameter: Vorlaststrom / pre-load current $I_{TAV(vor)}$, Spieldauer / cycle duration SD



Grenzstrom / Max. overload on-state current $I_{T(OV)M} = f(t)$, $v_{RM} = 0,8 V_{RRM}$

Beidseitige Kühlung / Two-sided cooling

Kühlkörper / Heatsink: K 0.05F

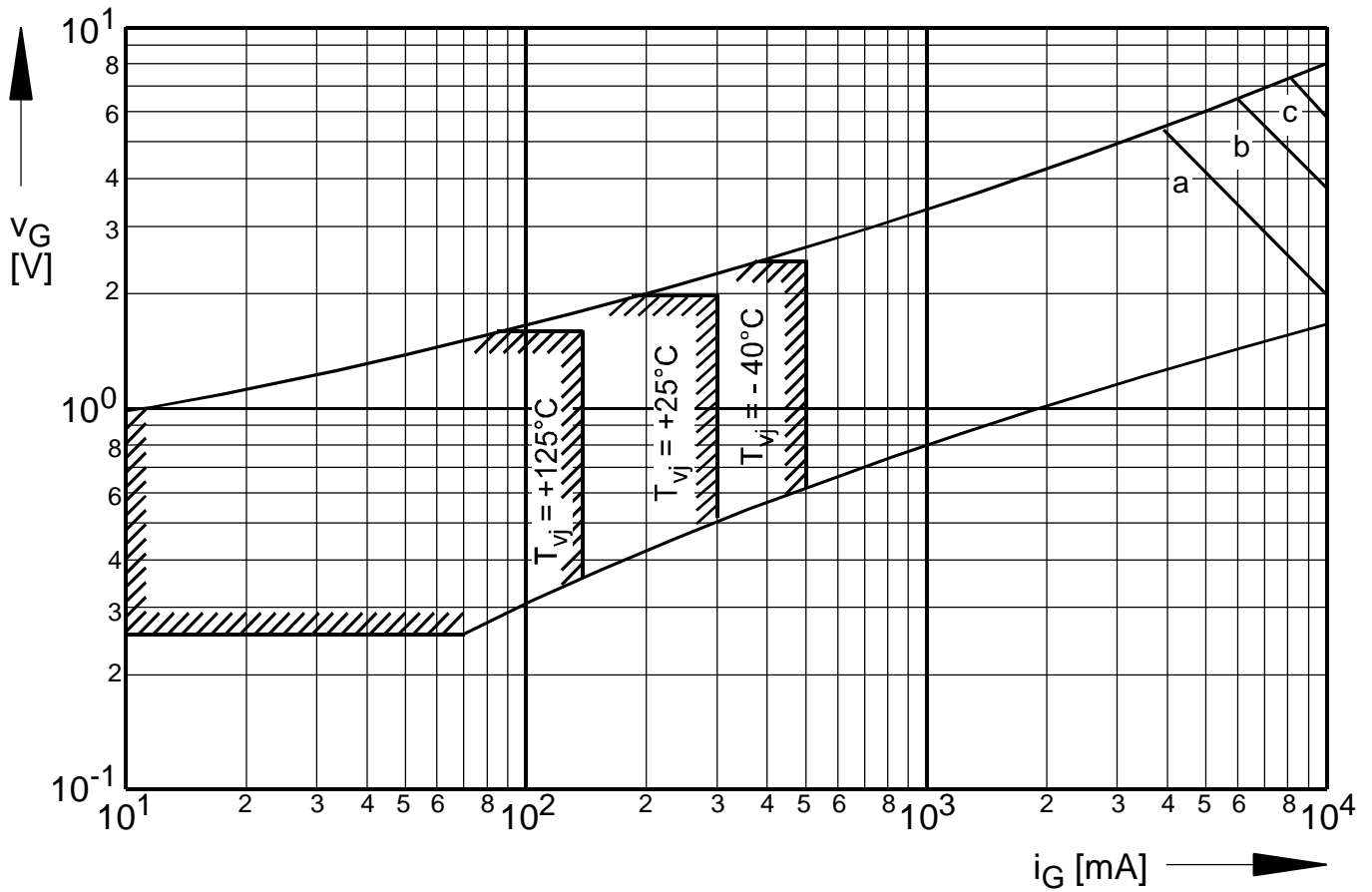
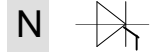
Belastung aus / Surge current occurs:

a - Leerlauf / No-load conditions

b - Betrieb mit Dauergrenzstrom / During operation at max. average on-state current I_{TAVM}

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Phase Control Thyristor

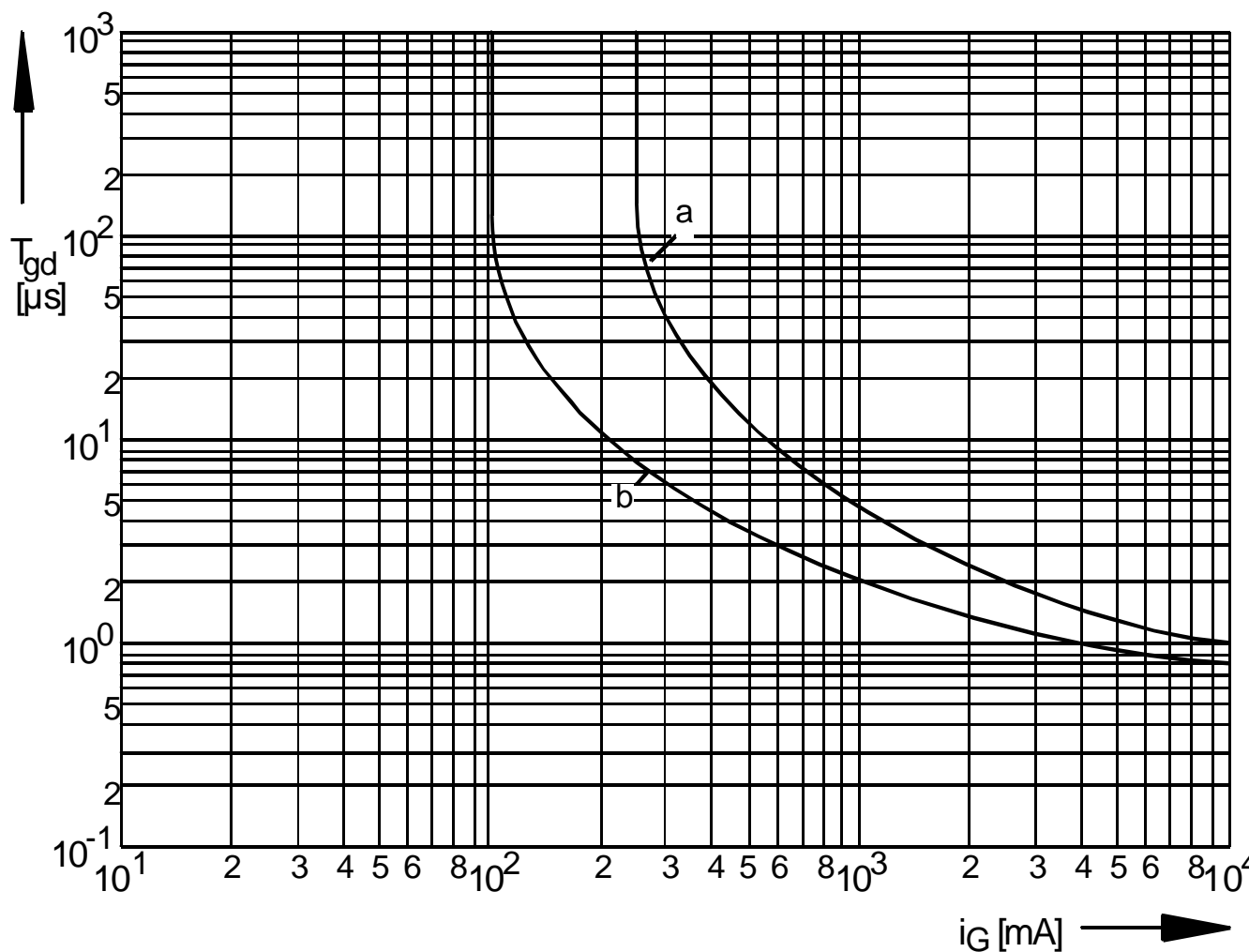
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Steuercharakteristik $v_G = f(i_G)$ mit Zündbereichen für $V_D = 6\text{ V}$
 Gate characteristic $v_G = f(i_G)$ with triggering area for $V_D = 6\text{ V}$

Höchstzulässige Spitzensteuerverlustleistung / Maximum rated
 peak gate power dissipation $P_{GM} = f(t_g)$:

a - 40 W/10ms b - 80 W/1ms c - 100 W/0,5ms d - 150 W/0,1ms

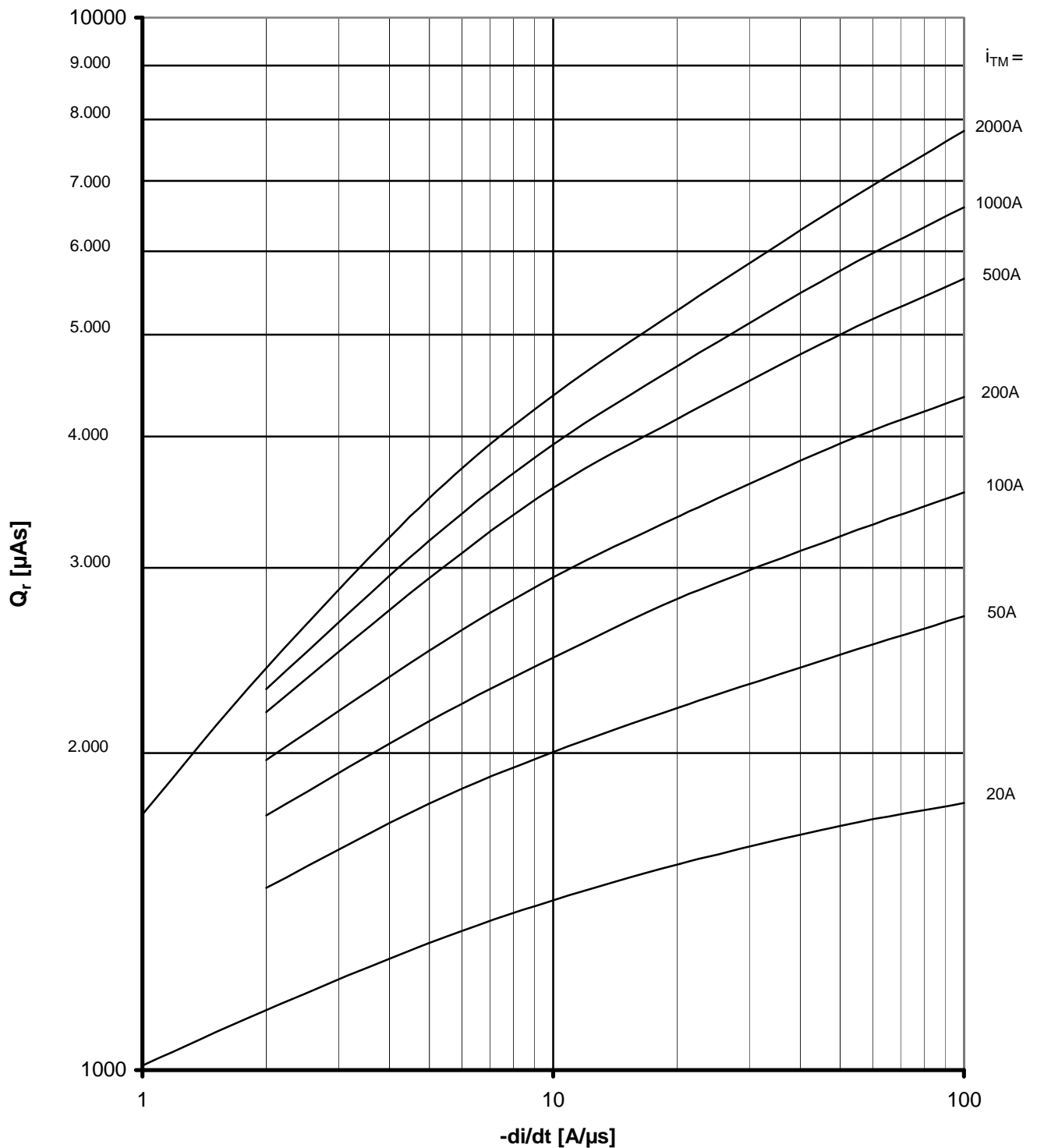


Zündverzug / Gate controlled delay time $t_{gd} = f(i_{GM})$

$T_{vj} = 25^\circ\text{C}, di_G/dt = i_{GM}/1\mu\text{s}$

a - maximaler Verlauf / limiting characteristic

b - typischer Verlauf / typical characteristic



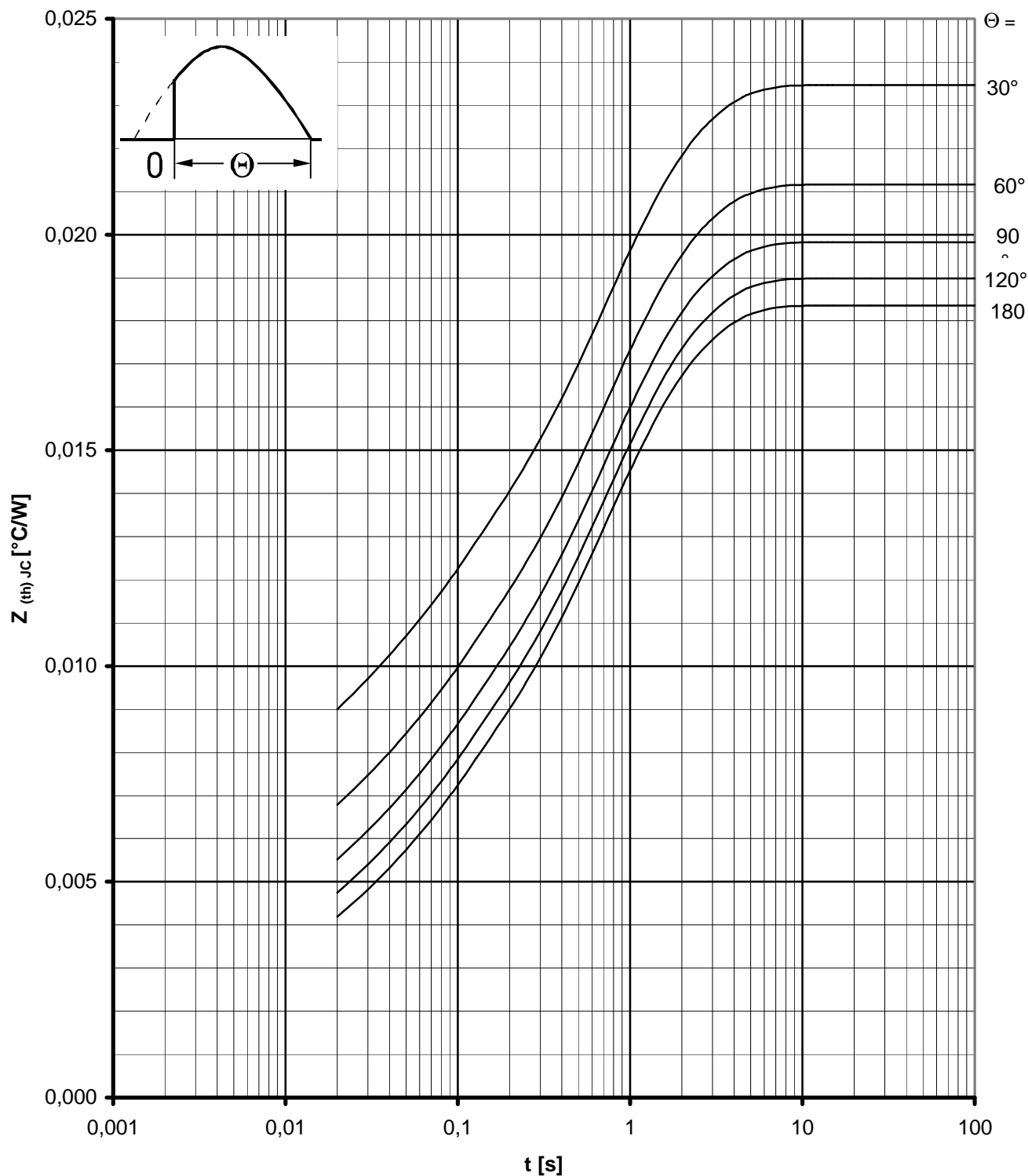
Sperrverzögerungsladung / Recovered charge $Q_r = f(di/dt)$

$T_{vj} = T_{vj} \text{ max}, V_R = 0,5 V_{RRM}, V_{RM} = 0,8 V_{RRM}$

Parameter: Durchlaßstrom / On-state current i_{TM}

Netz-Thyristor
Phase Control Thyristor

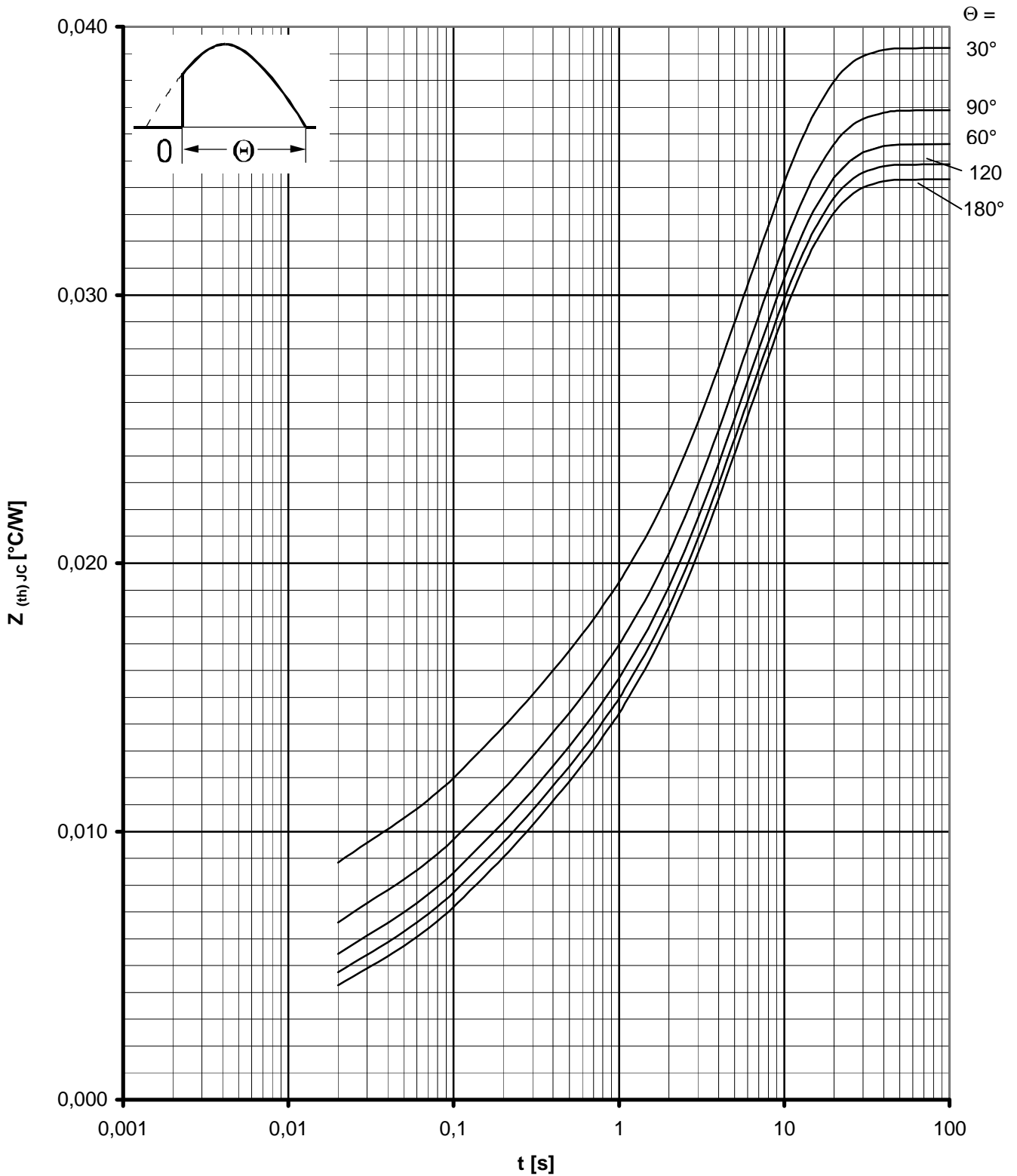
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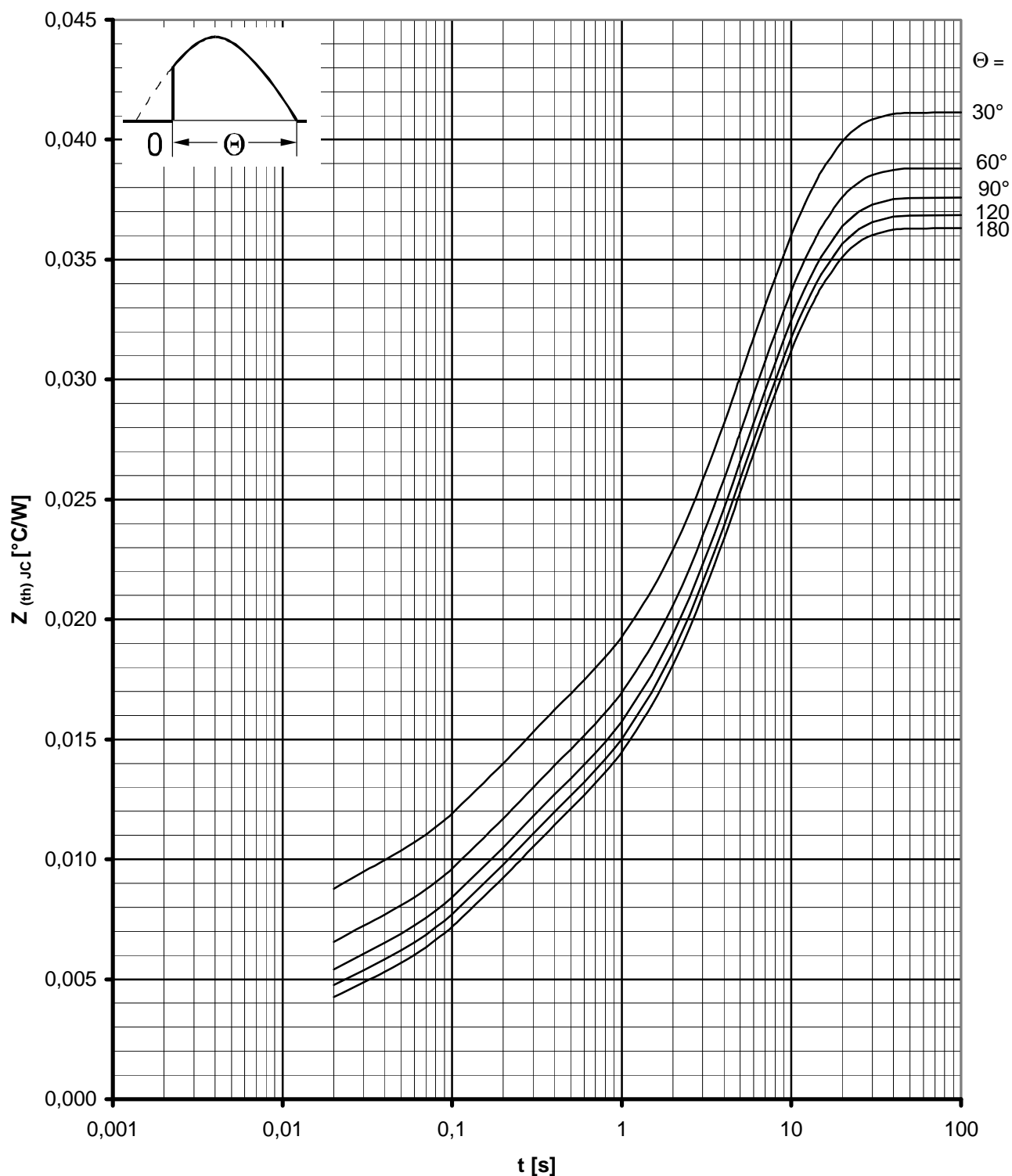
Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$

Beidseitige Kühlung / Two-sided cooling

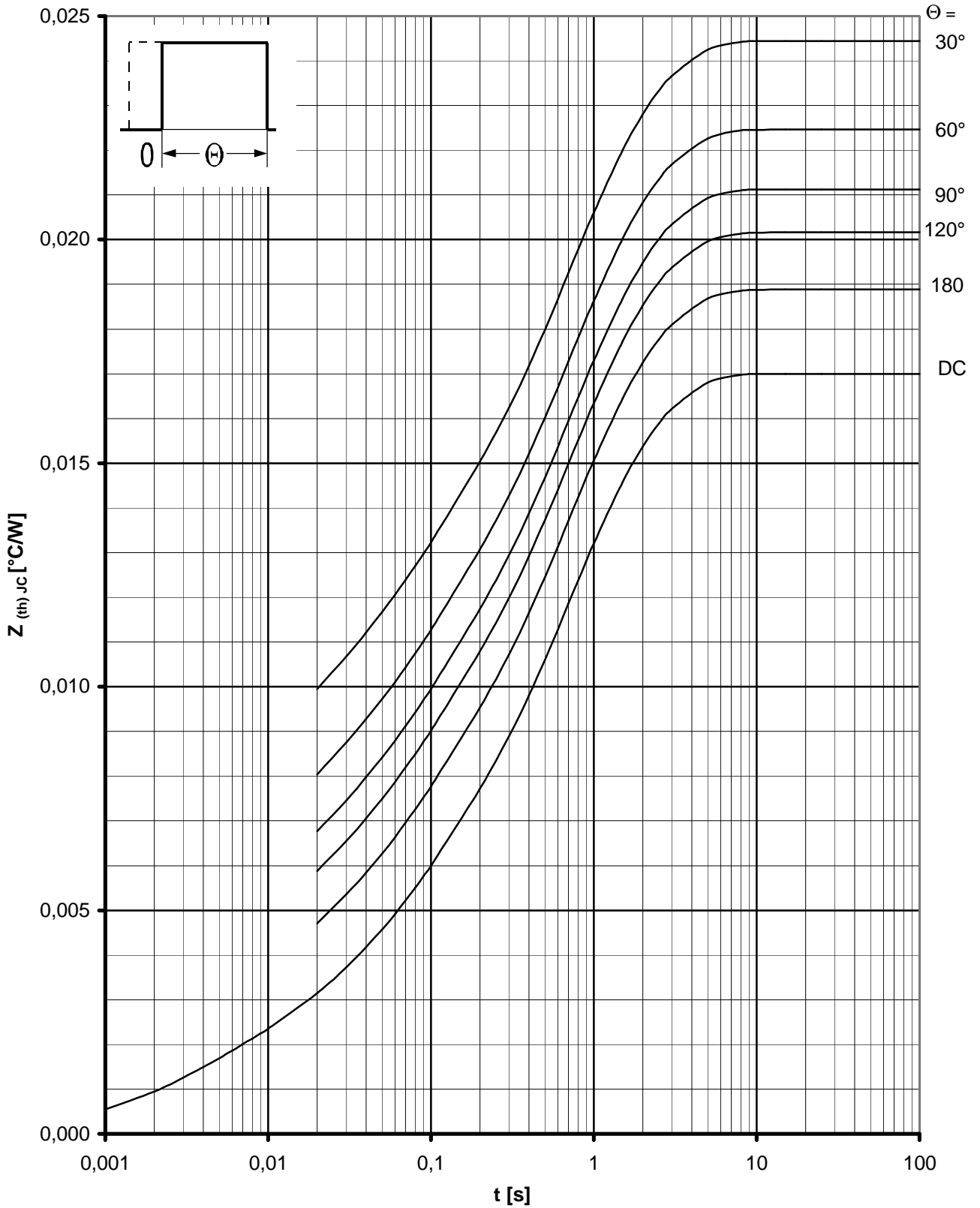
Parameter: Stromflußwinkel Θ / current conduction angle Θ



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$
 Anodenseitige Kühlung / Anode-sided cooling
 Parameter: Stromflußwinkel Θ / current conduction angle Θ



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$
 Kathodenseitige Kühlung / Cathde-sided cooling
 Parameter: Stromflußwinkel Θ / current conduction angle Θ



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$

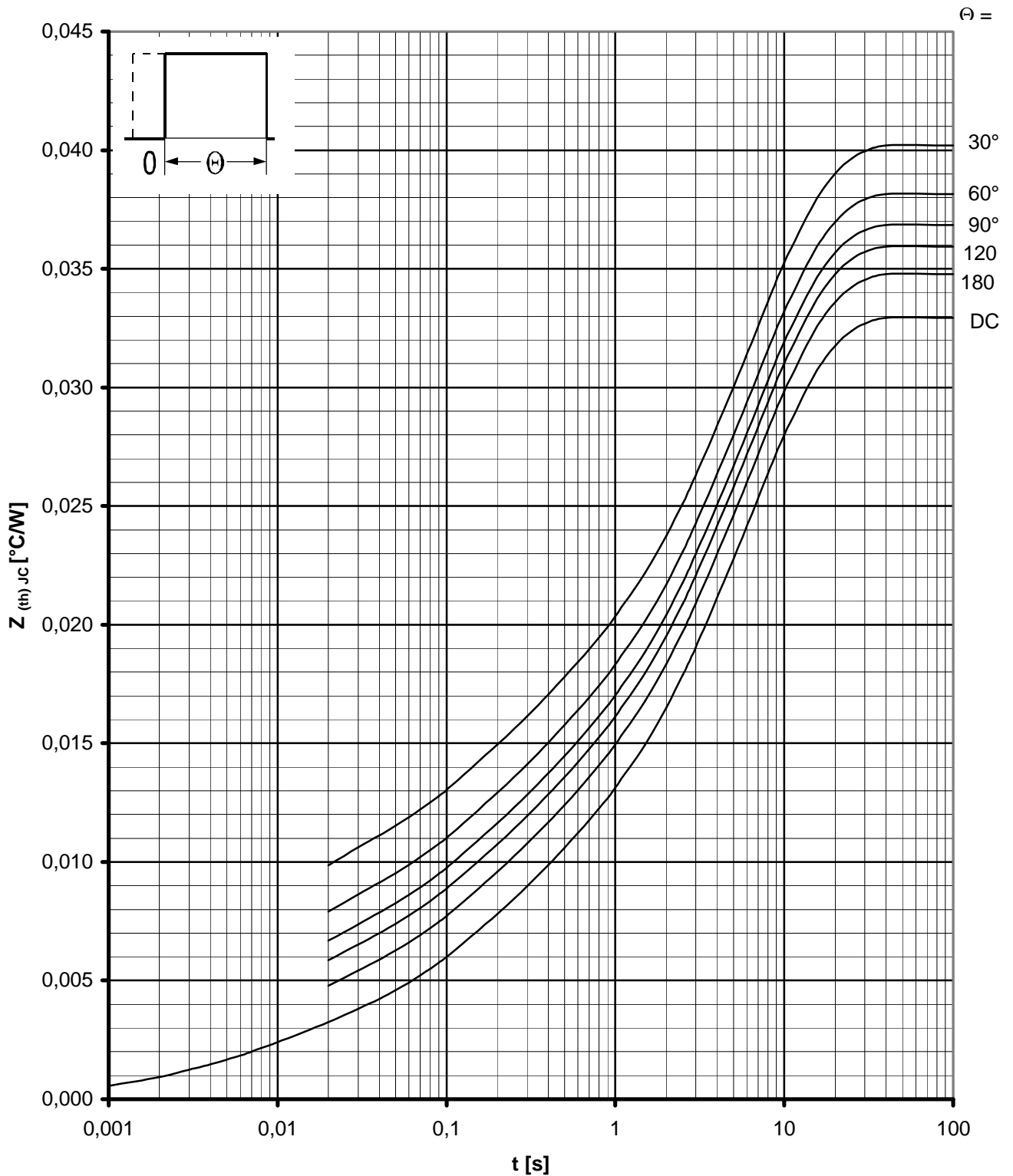
Beidseitige Kühlung / Two-sided cooling

Parameter: Stromflußwinkel Θ / current conduction angle Θ

Netz-Thyristor
Phase Control Thyristor

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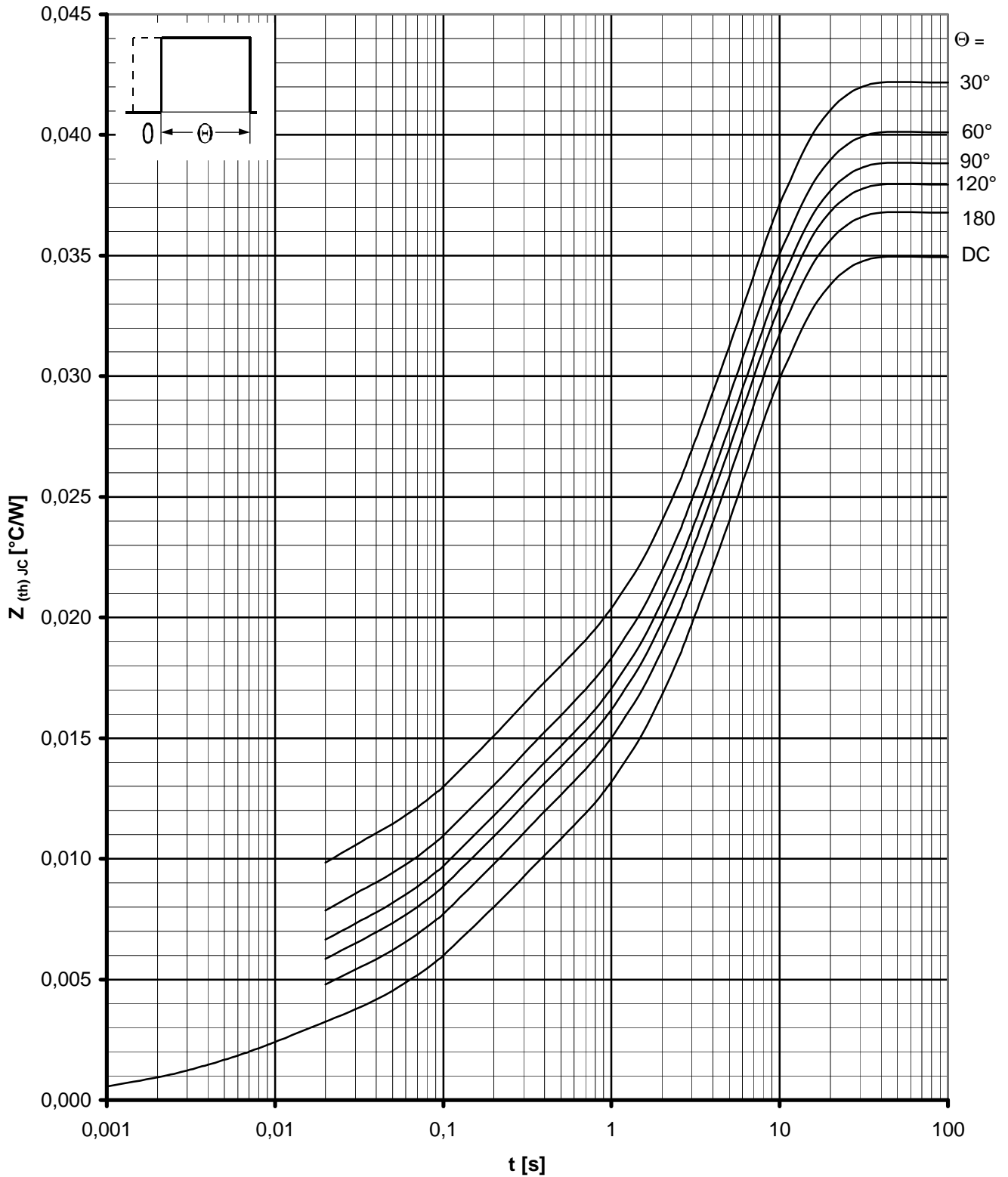
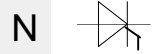
N



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th),JC} = f(t)$
 Anodenseitige Kühlung / Anode-sided cooling
 Parameter: Stromflußwinkel Θ / current conduction angle Θ

Netz-Thyristor
Phase Control Thyristor

T 1219 N 20...28



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$
 Kathodenseitige Kühlung / Cathode-sided cooling
 Parameter: Stromflußwinkel Θ / current conduction angle Θ